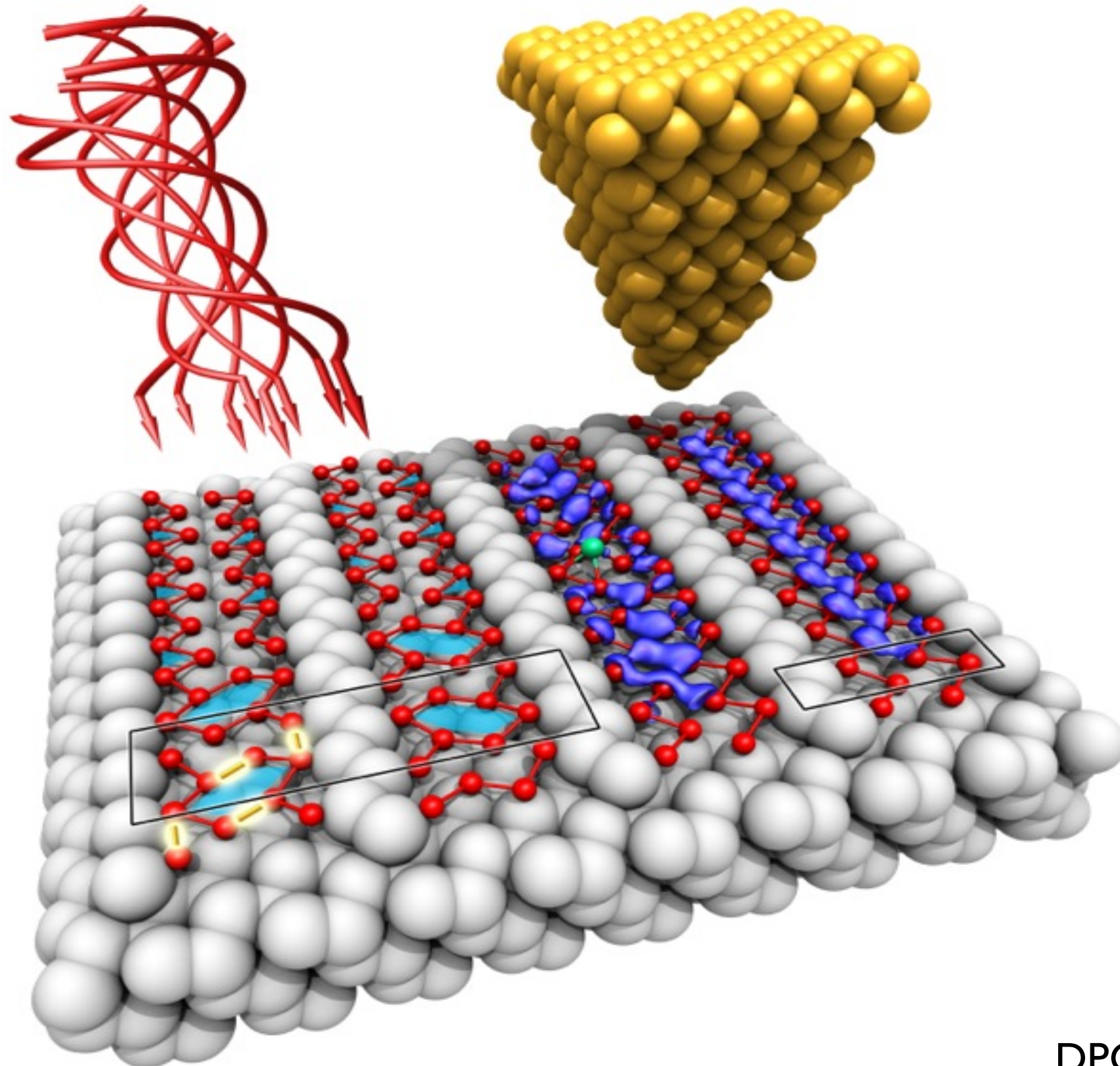




MAX-PLANCK-GESELLSCHAFT

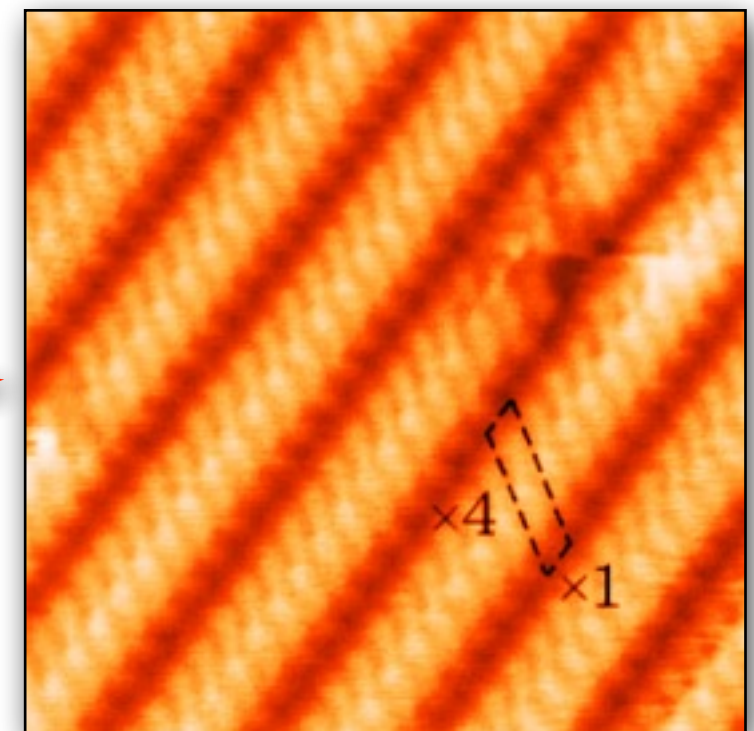
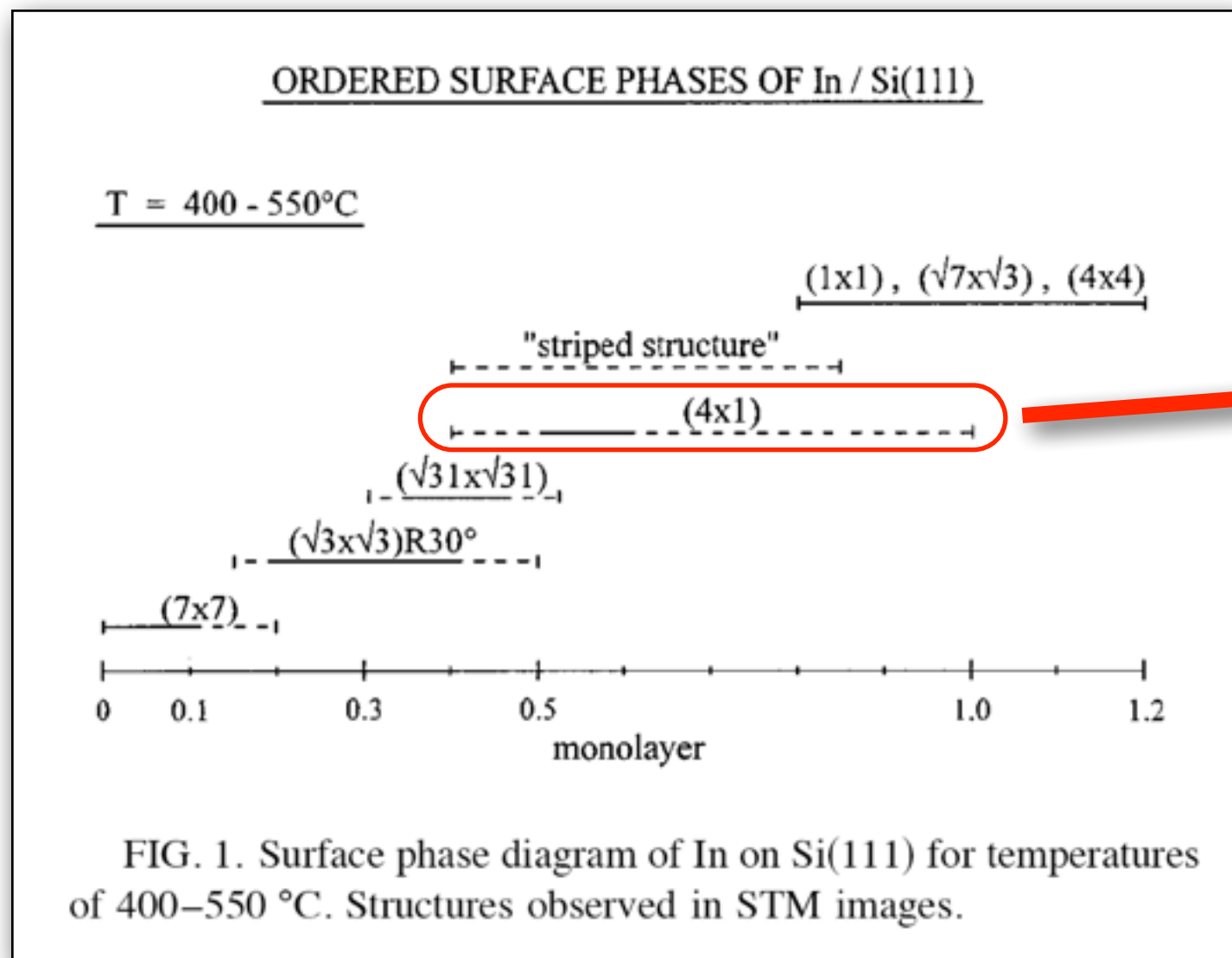
# In/Si(111)-(4x1)/(8x2): a fascinating model system for one-dimensional conductors

S. Wippermann, W. G. Schmidt



# In/Si(111)-(4x1): atomic scale wires on semiconductors

- Model system to study (quasi) 1D physics: In-induced (4x1) surface reconstruction of Si(111) [Landers and Morrison, J. Appl. Phys. 36, 1706 (1965)]
- At borderline between semiconducting low In coverage and metallic high In coverage phases



[H.W.Yeom *et al.*, PRL 82, 4898 (1999)]

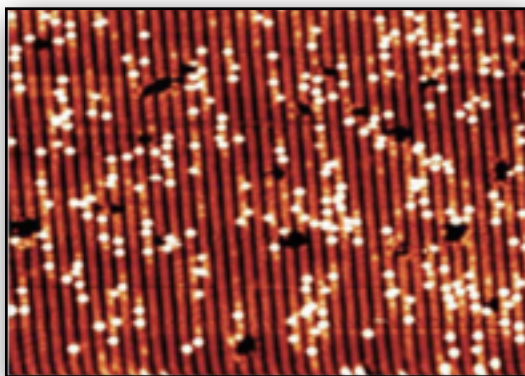
What is special about this system?



# Peierls Condensation?

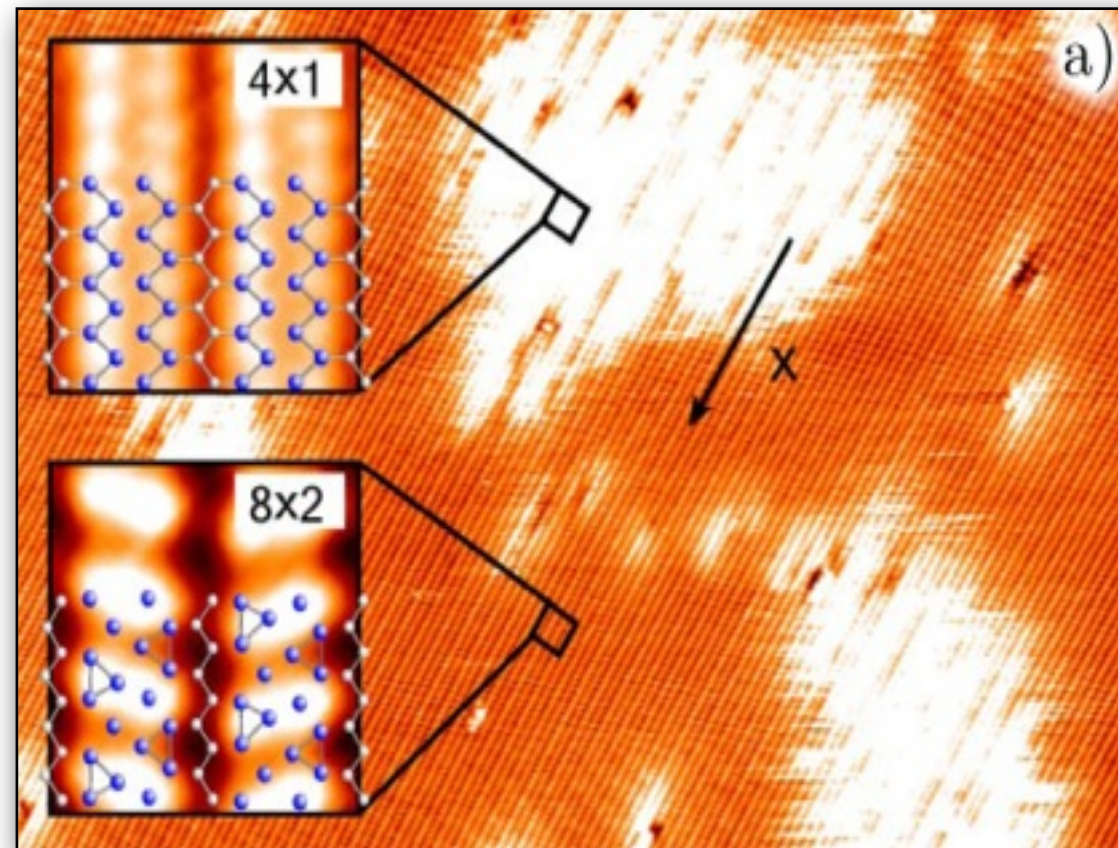
## ● Metallic RT (4x1) phase:

- structure basically understood
- real-world example for quasi-1D conductor



In 4x1 structure covered with 0.007 ML of Pb  
[Hupalo et al., **PRB** 76, 045415 (2007)]

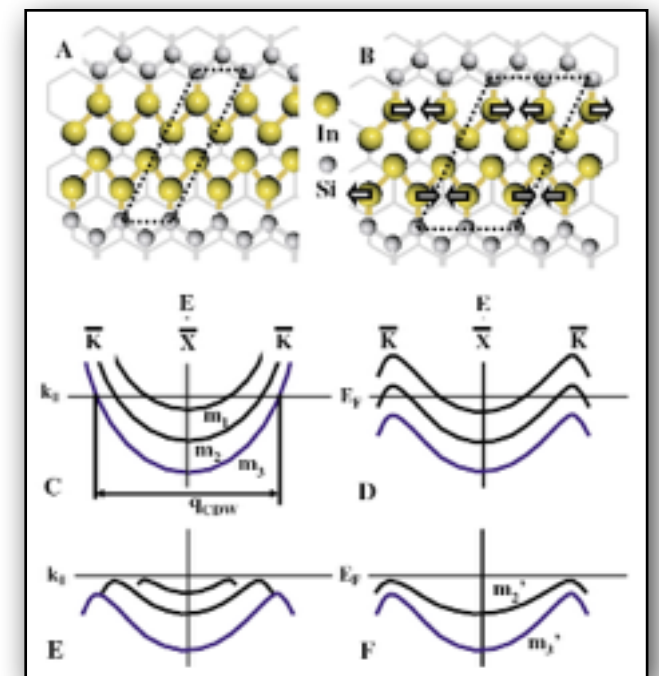
## ● Temperature-induced phase transition at ~120 K



[H.W.Yeom et al., **PRL** 95, 12601 (2005)]

## ● (presumably) semi-conducting LT (8x2) phase:

- structure not really understood
- mechanism of phase transition not really understood - Peierls instability??



[Ahn et al., **PRL** 93, 106401 (2004)]



# Competing structural models

**surface X-ray diffraction**

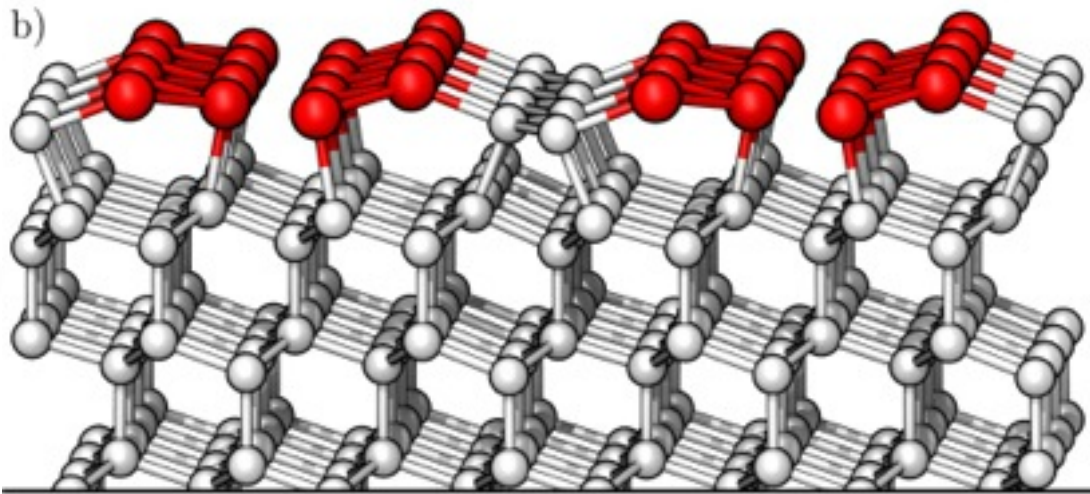
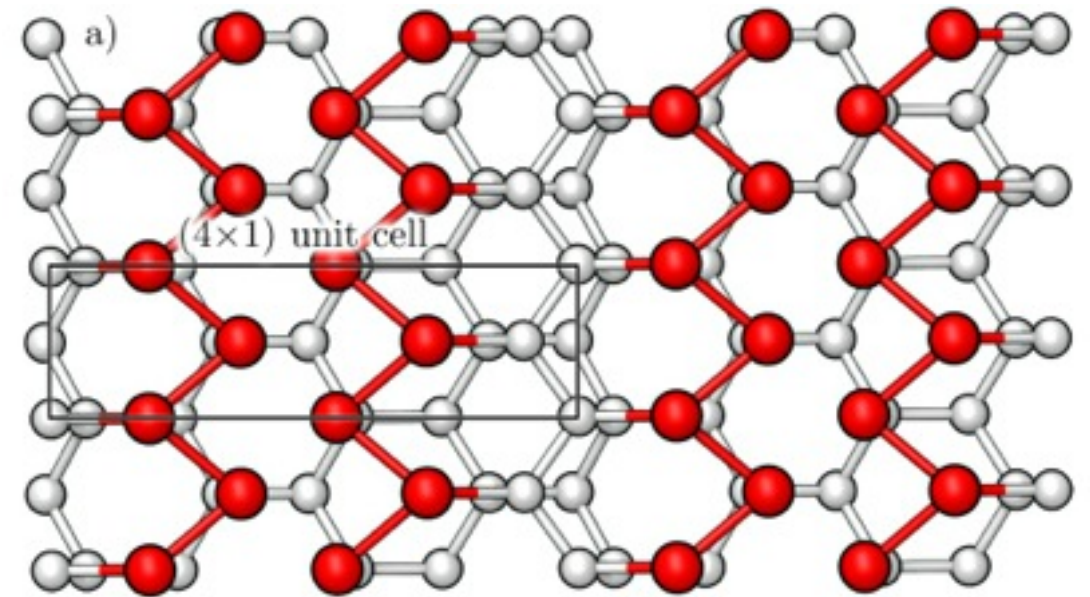
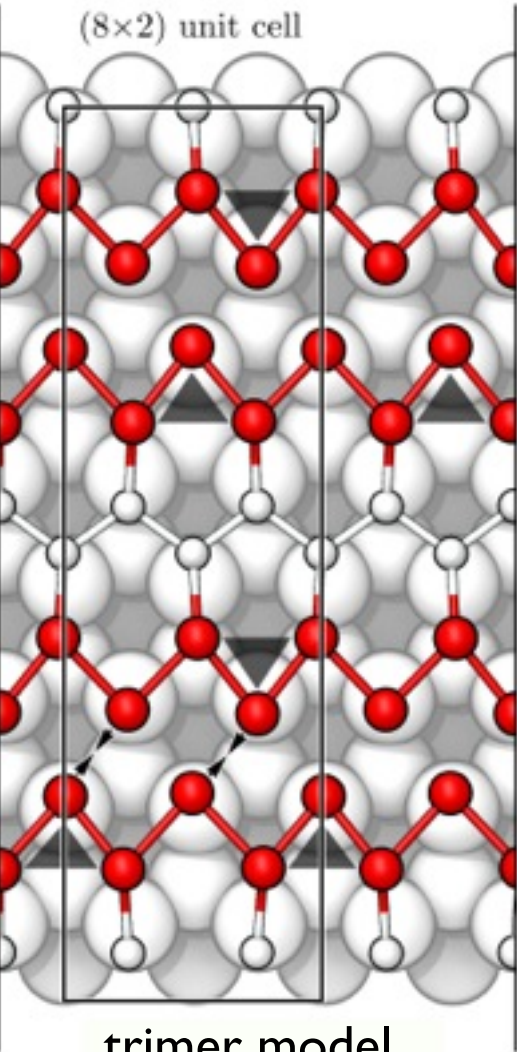
Kumpf et al. PRL 85, 4916 (2000)

**photoemission**

Yeom et al. PRB 65, 241307 (2002)

**DFT calculations**

Cho et al. PRB 64, 235302 (2001);  
Tsay, PRB 71, 035207 (2005);  
Lopez-Lozano et al., PRB 73, 035430 (2006);  
Cho and Lee, PRB 76, 033405 (2007);  
...



**surface X-ray diffraction**

Bunk et al. PRB 59, 12228 (1999)

**DFT calculations**

Cho et al. PRB 64, 235302 (2001);  
Miwa and Srivastava, Surf. Sci. 473, 123 (2001);  
Nakamura et al. PRB 63, 193307 (2001);  
WGS et al. PRB 68, 035329 (2003);  
...

GGA

ground state

LDA

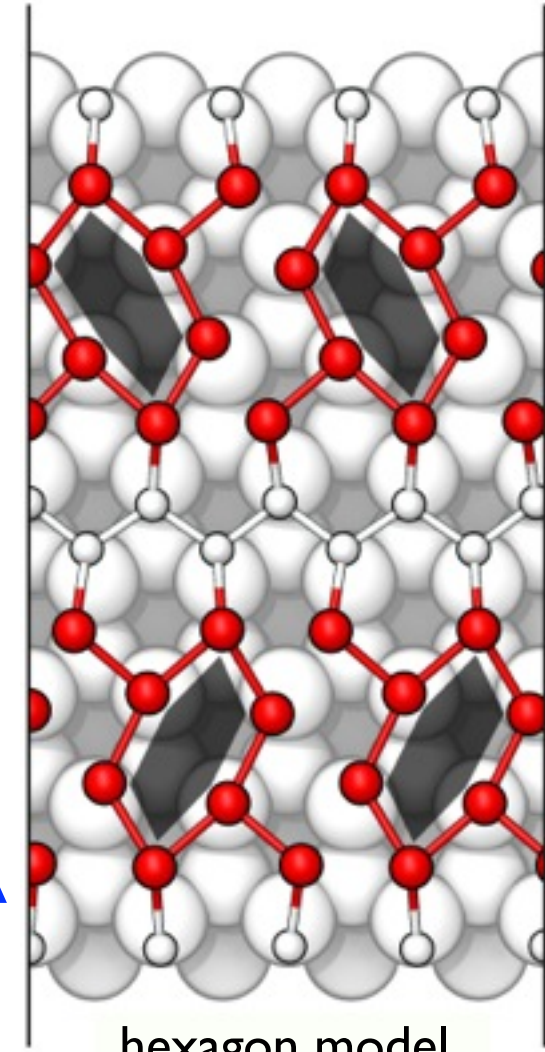
[S. Wippermann, WGS et al., PRL 98, 026105 (2007)]

**DFT calculations**

Gonzalez et al. PRL 96, 136101 (2006)

**positron diffraction**

Fukaya et al. Surf. Sci. 602, 2448 (2008)





# Obtain Structure from Reflectance Anisotropy Spectroscopy

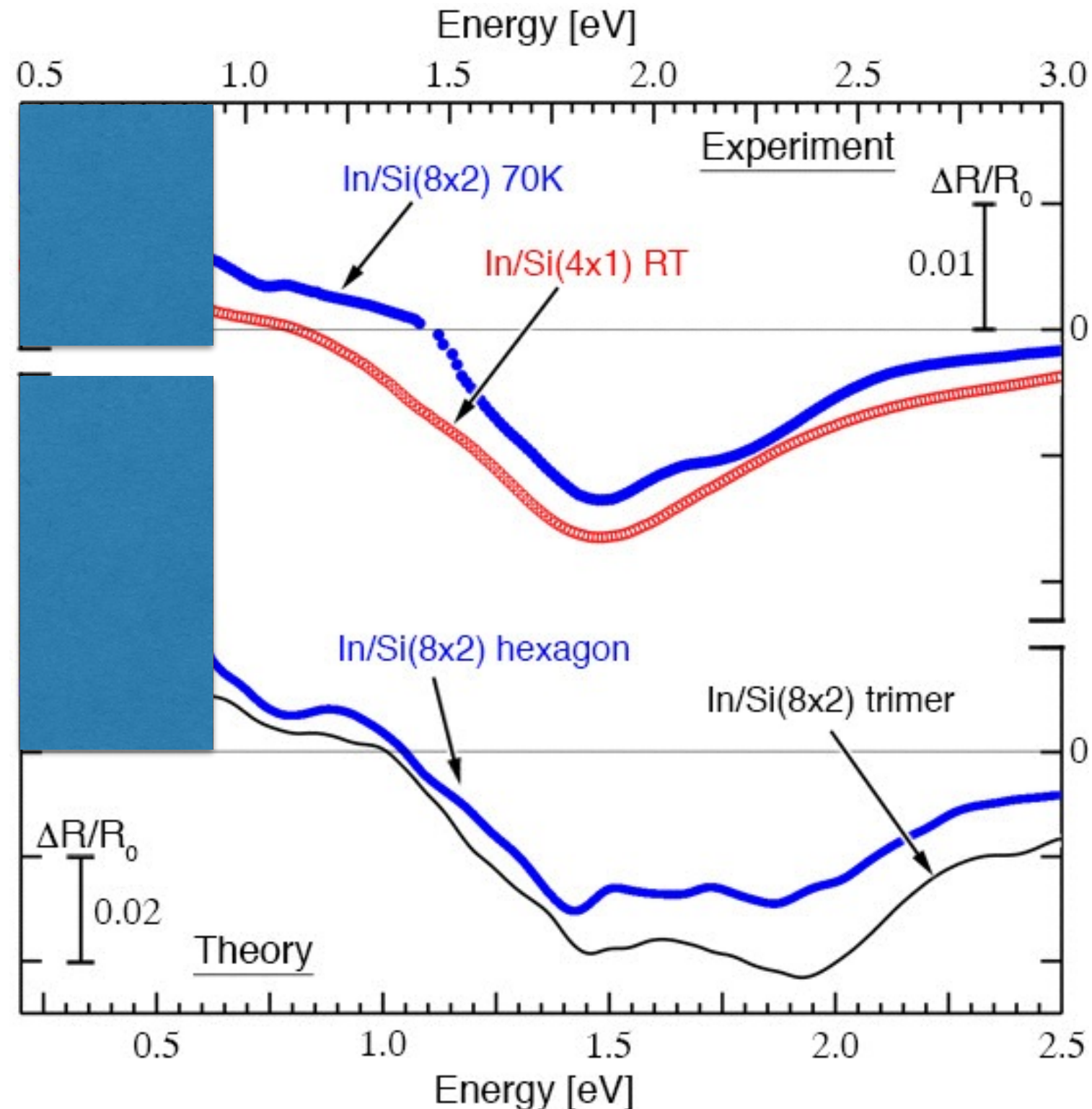
- Shoulder observed experimentally at 2 eV upon cooling, signature for phase transition?

➡ **No, reproduced by both hexagon & trimer models**

- Mid-infrared regime: anisotropic Drude tail replaced by two distinct peaks upon cooling

- Only hexagon model agrees with measured data**

➡ **Structure determined! Now understand mechanism of phase transition**



# Phonon Modes: Theory vs. Experiment

THEORY $\omega_0$ [ $\text{cm}^{-1}$ ]			EXPERIMENT $\omega_0$ [ $\text{cm}^{-1}$ ]		
(4×1)	→	(8×2)	(4×1)	→	(8×2)
22	→	20	31 ± 1	→	21 ± 1.6
		27			28 ± 1.3
		hexagon rotary mode			
44	→	47	36 ± 2	→	41 ± 2
51	→	53	52 ± 0.6	→	57 ± 0.7
62	→	58, 69	61 ± 1.3	→	62, 69 ± 1.5
65, 68	→	70, 69, 78, 82	2.72 ± 3.3	→	83 ± 2.3
100, 104	→	97, 106, 113, 142	105 ± 1	→	100–130
129, 131	→	137, 142	118 ± 1	→	139 ± 1.2
143, 145	→	139, 145, 146, 147	2.148 ± 7	→	139, 2.154 ± 2
28	→	18, 19	28 ± 0.9	→	2.23.5 ± 0.8
shear mode					
→ antisym./sym. shear mode					
		35			3.42 ± 3.5
		51			2.59 ± 3
		75			69 ± 1.5
		82			85 ± 1.7

TABLE I: Calculated  $\Gamma$ -point frequencies for strongly surface localized A' (upper part) and A'' phonon modes (lower part) of the Si(111)-(4×1)/(8×2)-In phases in comparison with experimental data [26]. The symmetry assignment of the (8×2) modes is only approximate, due to the reduced surface symmetry.

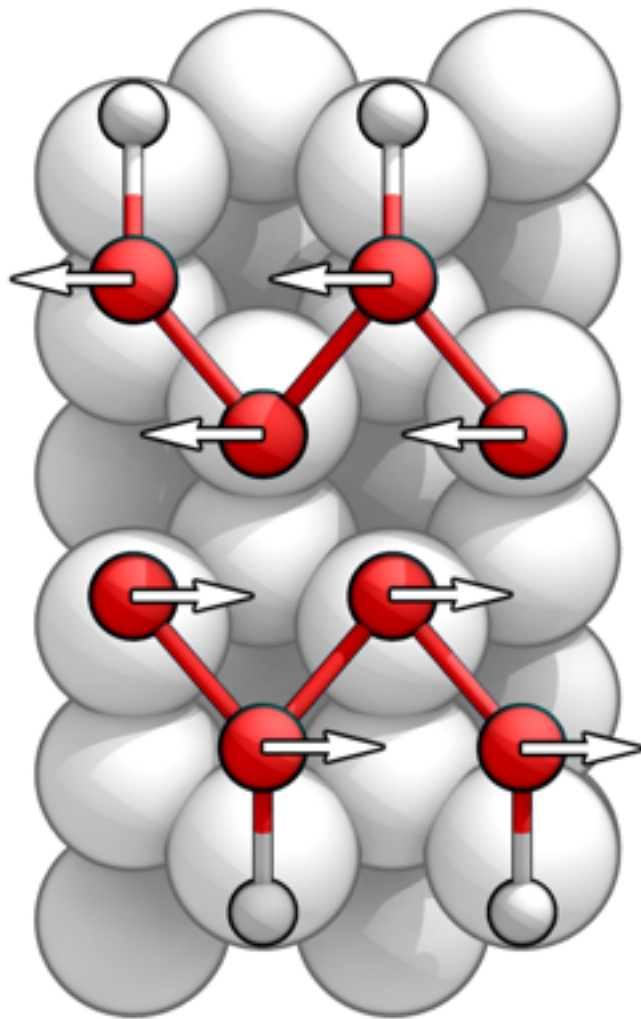
- calculate phonon frequencies and modes
- in general good agreement with experiment [K Fleischer et al., Phys. Rev. B 76, 205406 (2007)]
- (4×1) and (8×2) structures are well defined local minima on potential energy surface
- no soft (imaginary) modes at T = 0 K
- experimental spectra and assigned calculated phonon modes on backup slide



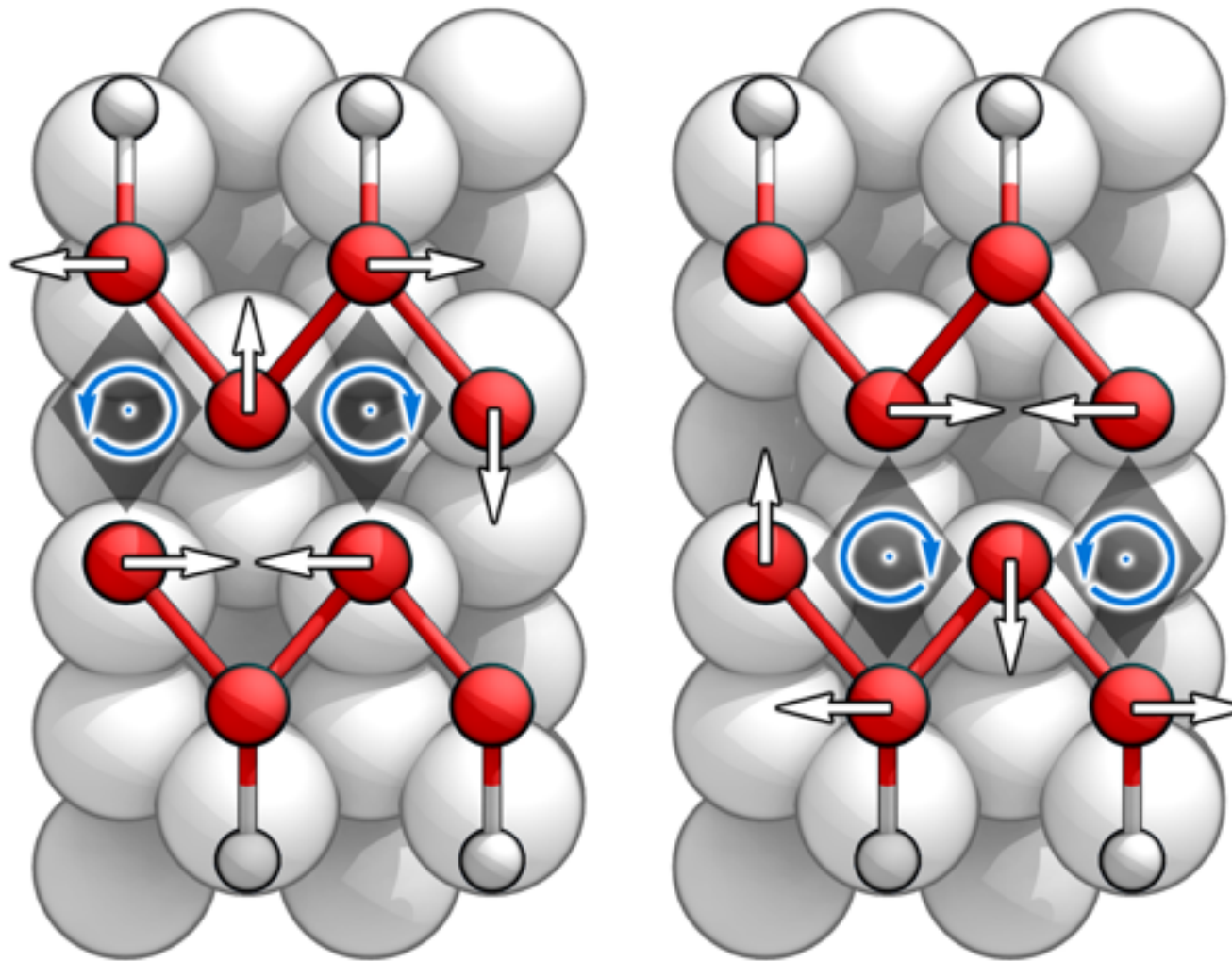
# Transition path: phonon modes show the way

- $(4 \times 1) \leftrightarrow (8 \times 2)$  transition path well-described by low energy phonon eigenvectors
- Linear combination of  $(4 \times 1)$  shear and trimer modes yield  $(8 \times 2)$  hexagon
- $(8 \times 2)$  shear and hexagon modes yield  $(4 \times 1)$  ideal reconstruction
- Rearrangement of In atoms leads to formation of new bonds => Peierls instability?

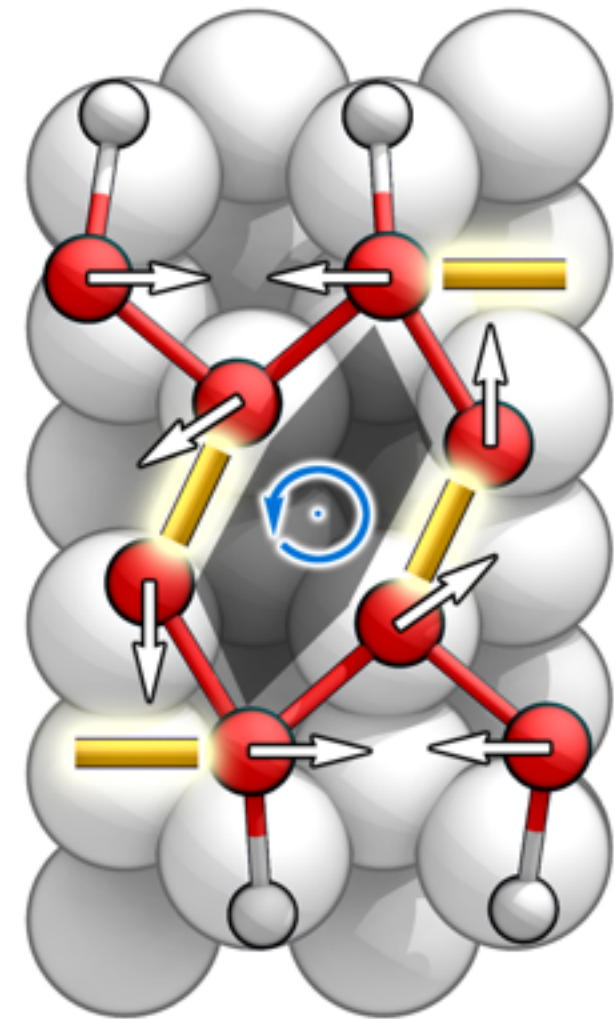
shear mode: 3.4 meV



trimerization modes: 2.1 meV

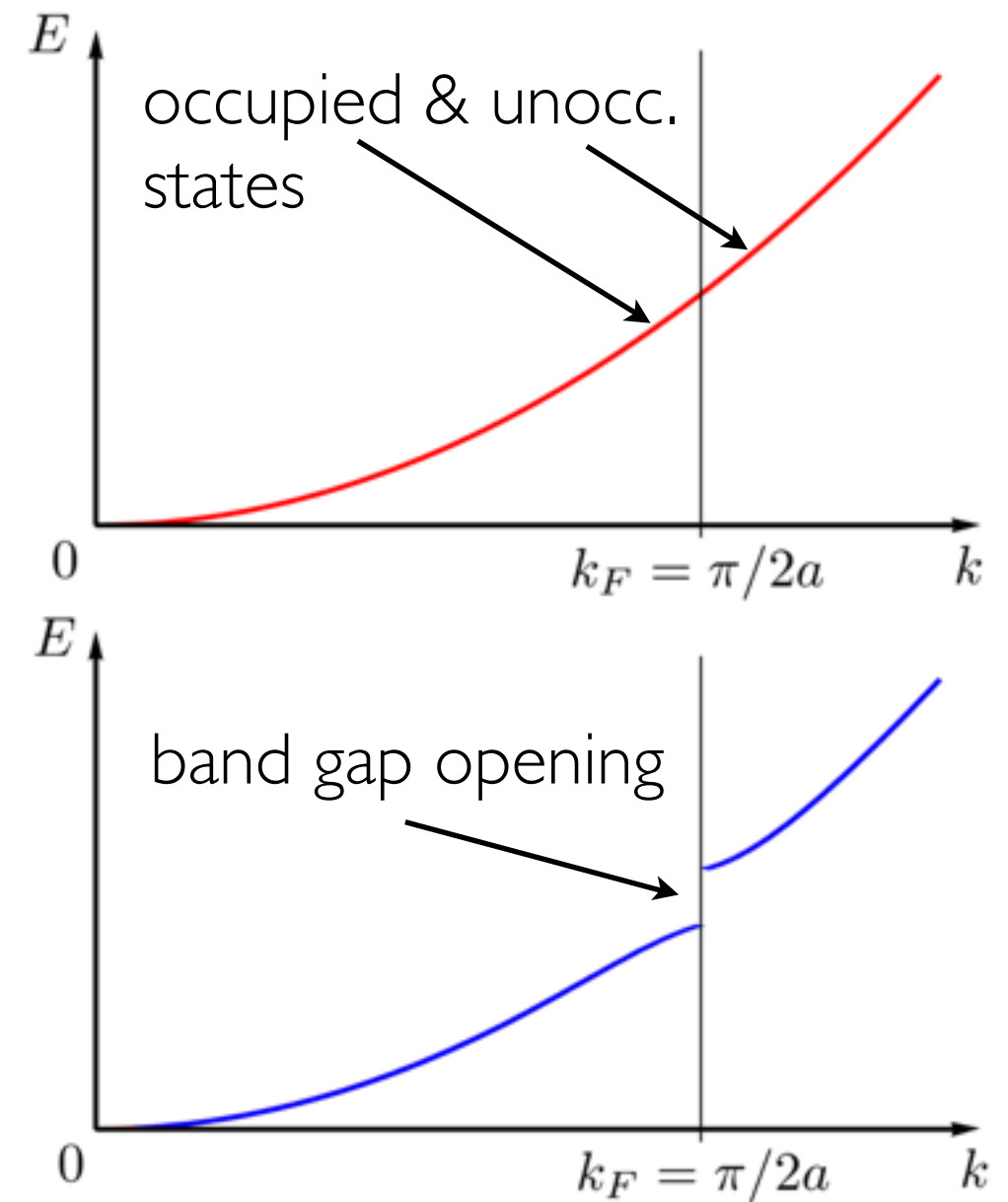
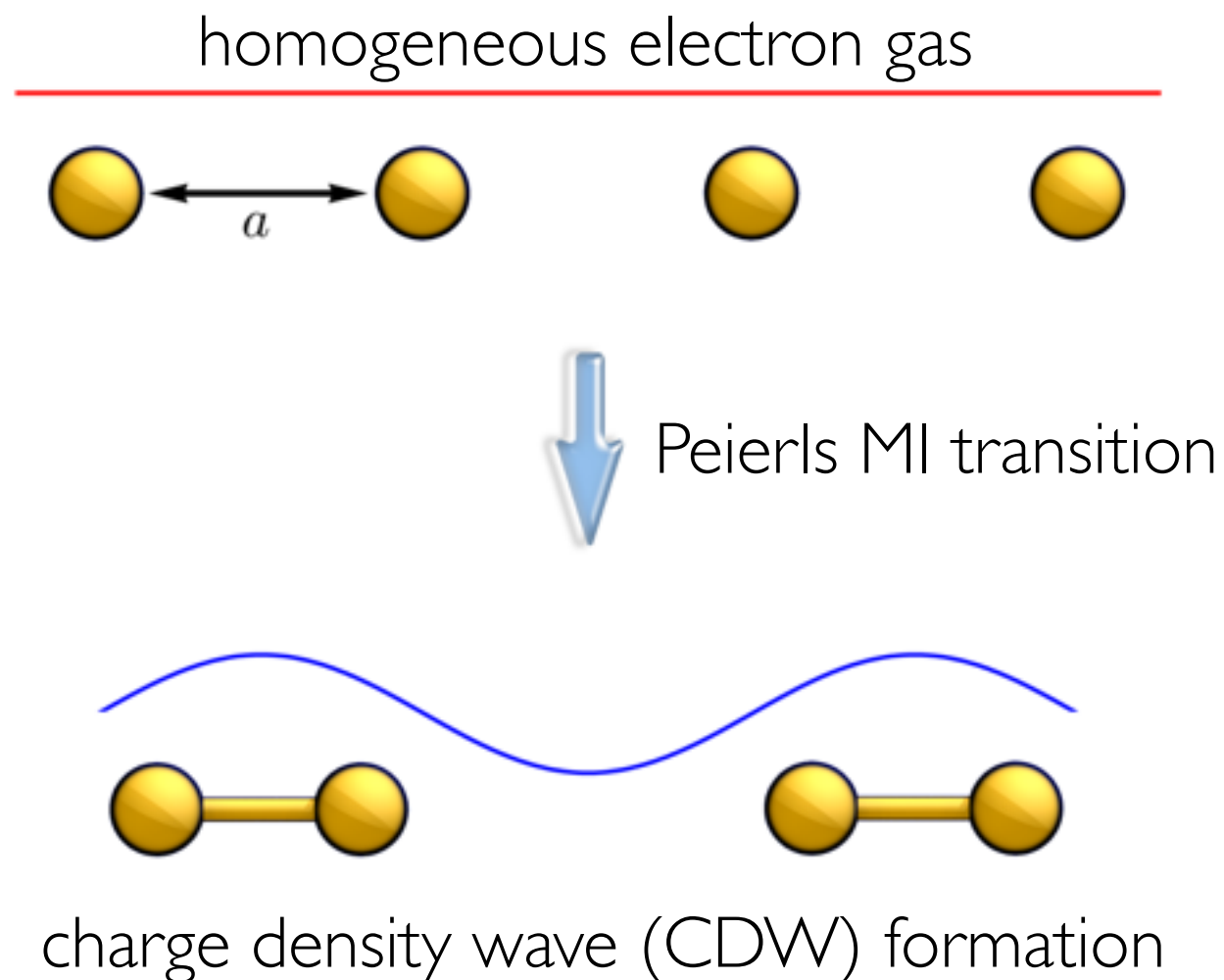


hexagon mode: 3.4 meV



# Peierls instability

- 1D-metals *a priori* unstable
- Free energy lowered by phonon-driven metal-insulator (MI) transition

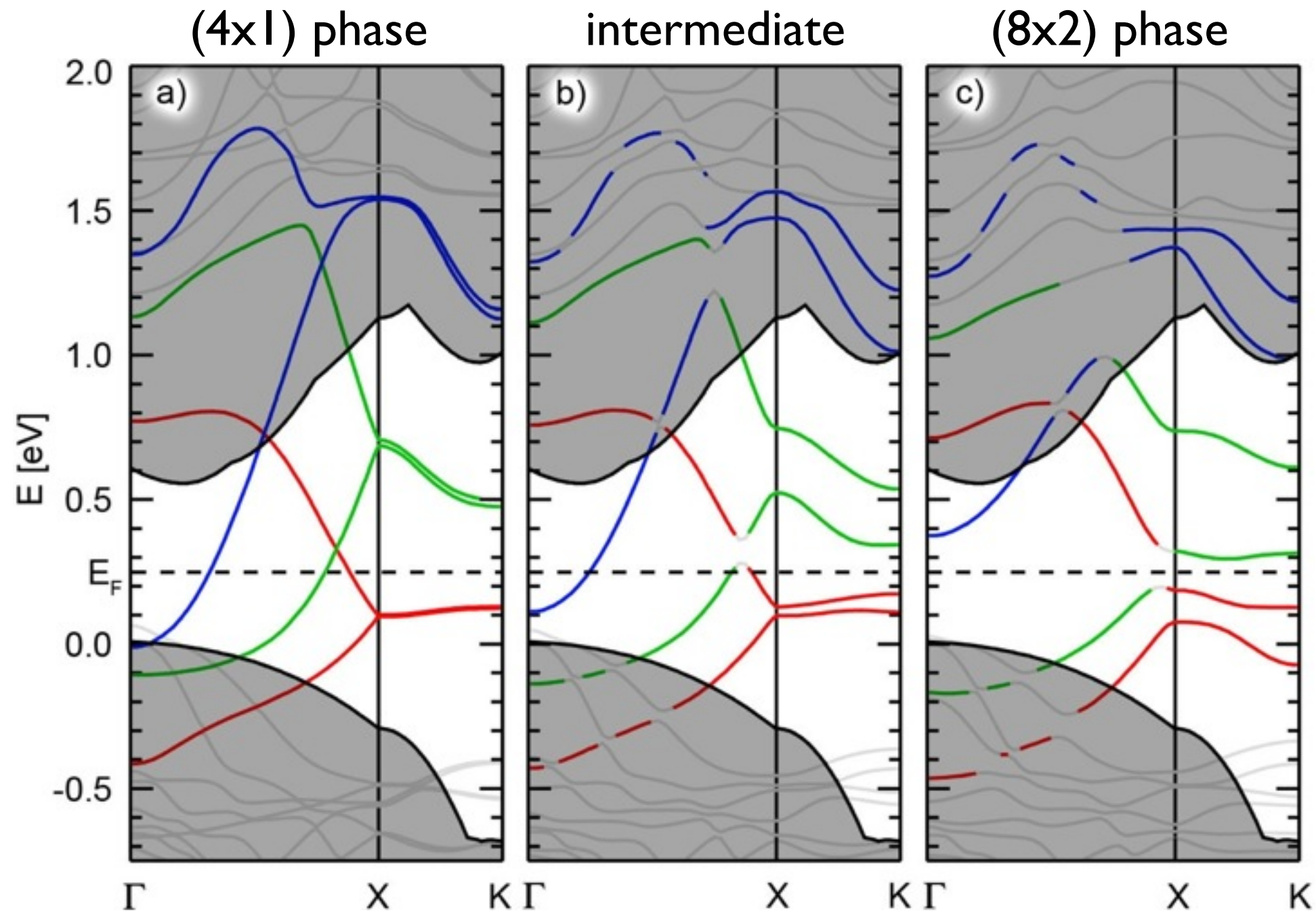




# No Peierls transition in In/Si(111) in the original sense

- Follow transition path defined by soft phonon eigenvectors and calculate band structures

- Formation of band-gap leads to energy gain *in analogy* to Peierls transition, but poor nesting and does not occur at edge of Brillouin zone



Why phase transition from semiconducting (8x2) ground state to metallic (4x1)?

=> Calculate free energy at finite temperature

# Atomistic Thermodynamics

- calculate **free energy** from *first principles*

$$F(V, T) = F_{el}(V, T) + F_{vib}(V, T)$$

$$F_{el} = E_{tot} - TS_{el}$$

- approximate the total energy  $\mathbf{E}_{tot}$  by the zero-temperature DFT value and calculate the electronic entropy  $\mathbf{S}_{el}$  from

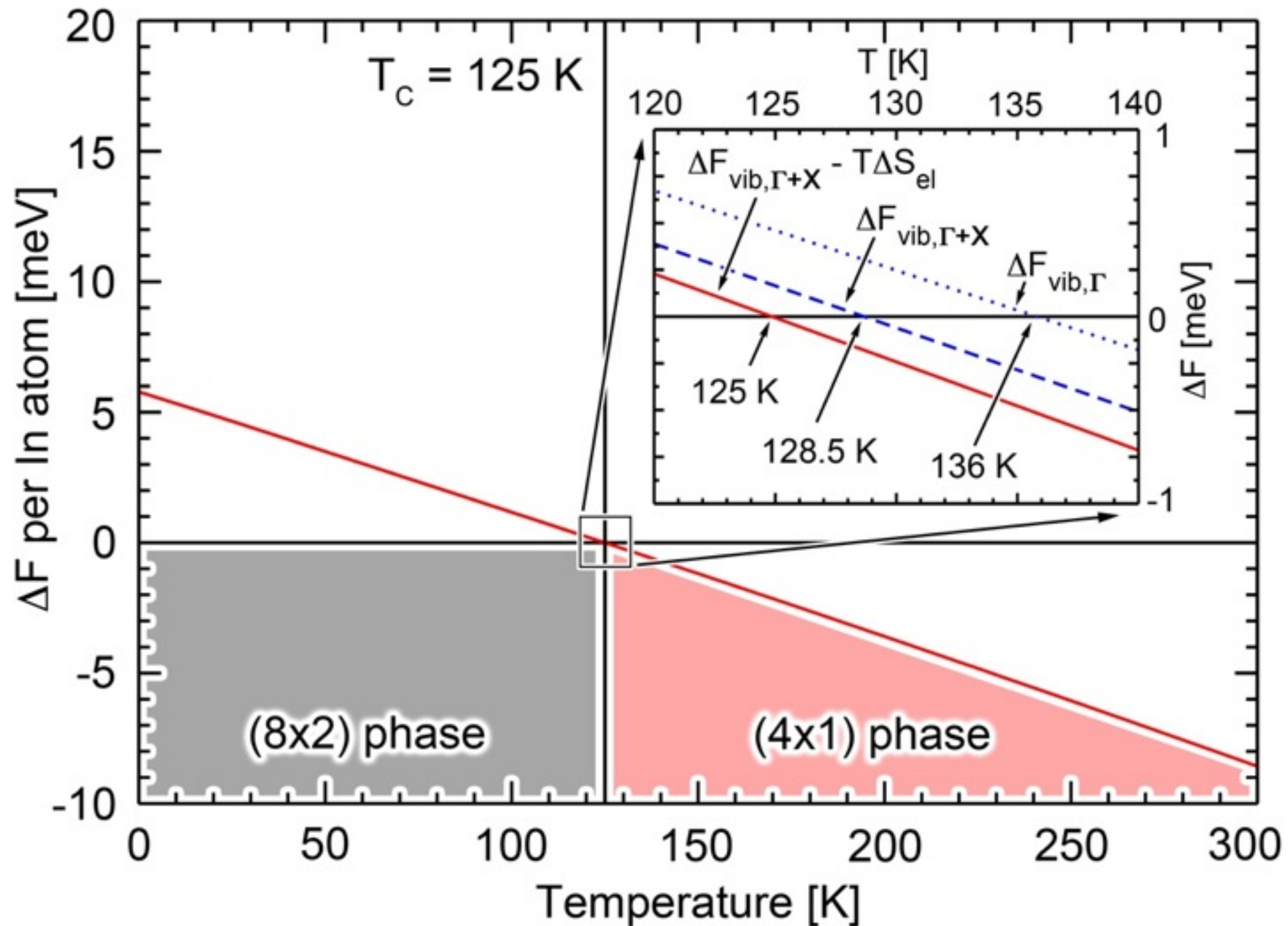
$$S_{el} = k_B \int dE \, n_F [f \ln f + (1 - f) \ln(1 - f)]$$

- vibrational entropy of the periodically repeated supercell with volume  $\Omega$  is calculated in harmonic approximation

$$F_{vib} = \frac{\Omega}{8\pi^3} \int d^3\mathbf{k} \sum_i \left( \frac{1}{2} \hbar \omega_i(\mathbf{k}) + k_B T \ln(1 - e^{-\frac{\hbar \omega_i(\mathbf{k})}{k_B T}}) \right)$$

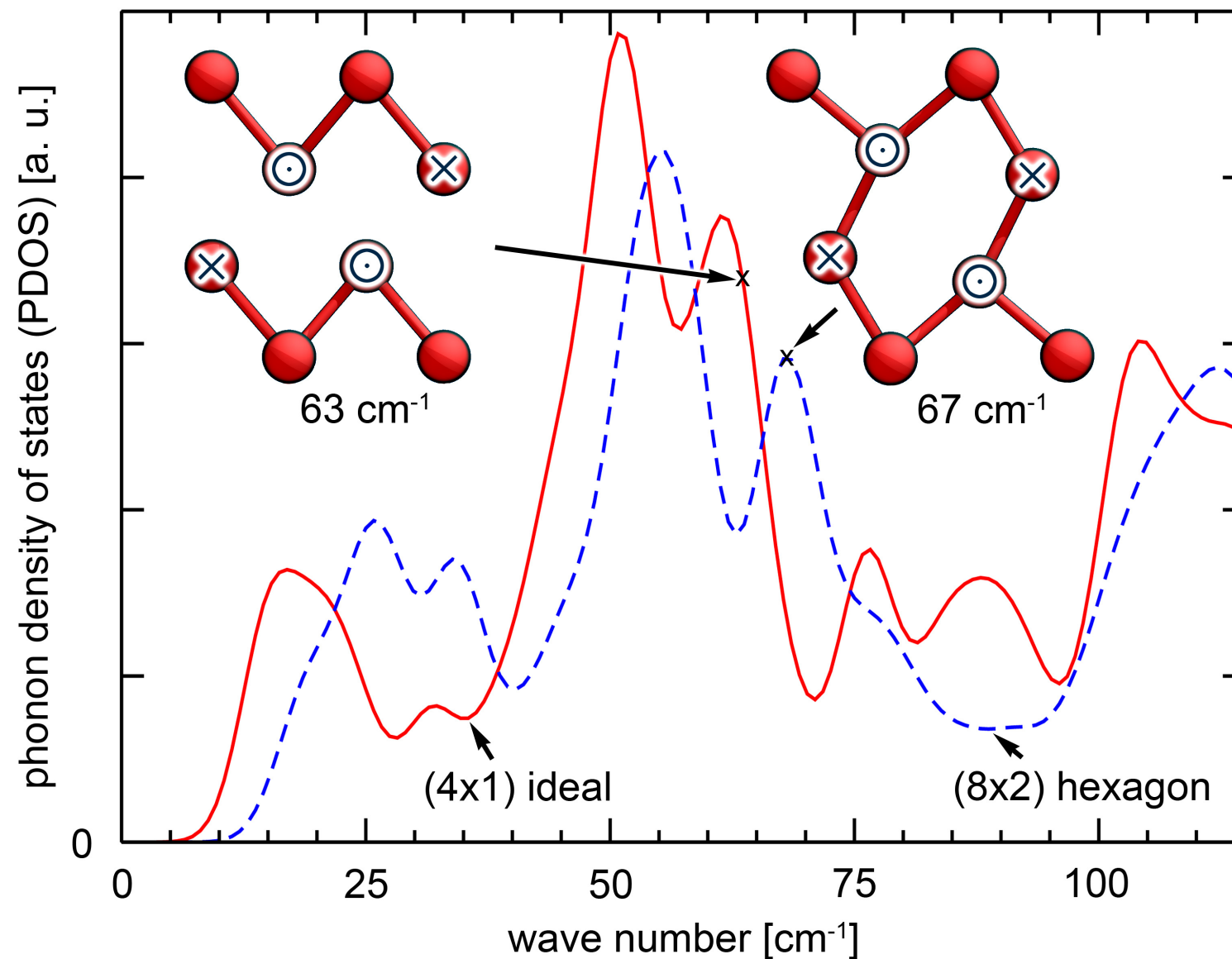


# Free energy of the (4x1) and (8x2) phase ...



- ... explains phase transition at 125 K (experiment: 120K)
- Simple explanation possible?

# Harder phonons counterbalance band structure energy gain

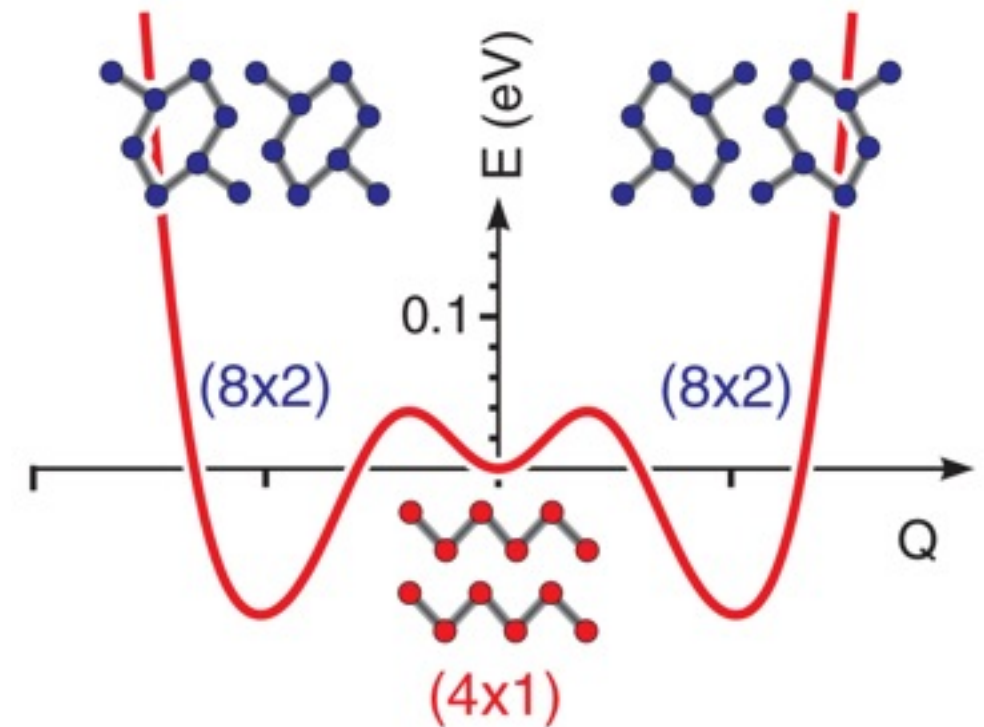
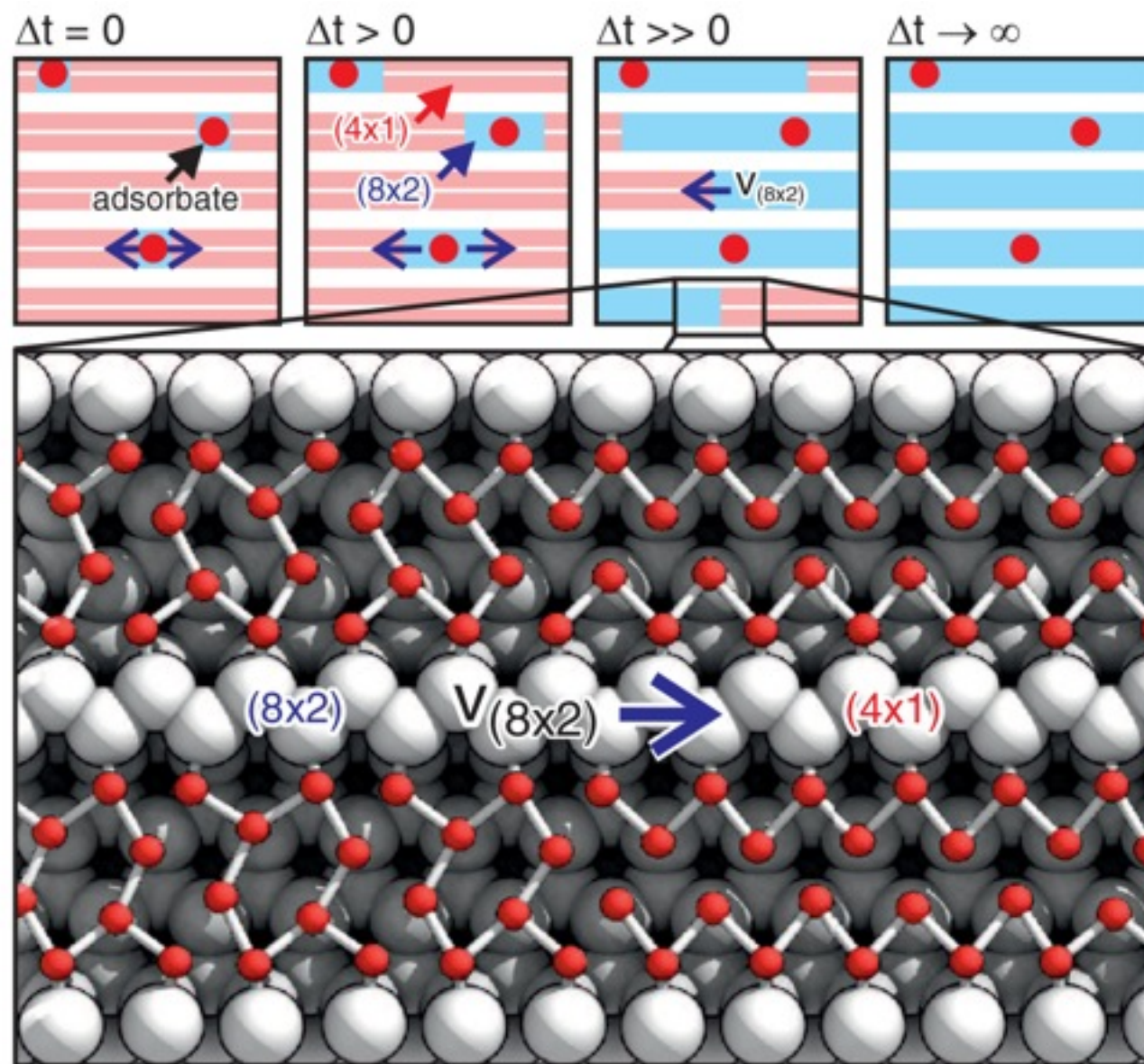


- Hardening of phonon modes upon bond formation in (8x2) hexamer model lowers vibrational entropy...
- ...compared to metallic (4x1) model with soft bonds
- For finite temperatures entropy contributions dominate and cause (8x2)  $\rightarrow$  (4x1) phase transition



# Phase transition triggered by condensation nuclei

- energetics along  $(4 \times 1) \rightarrow (8 \times 2)$  transition path obtained from phonon calculations
- hampered by energy barrier of 20 meV per  $(8 \times 2)$  unit cell



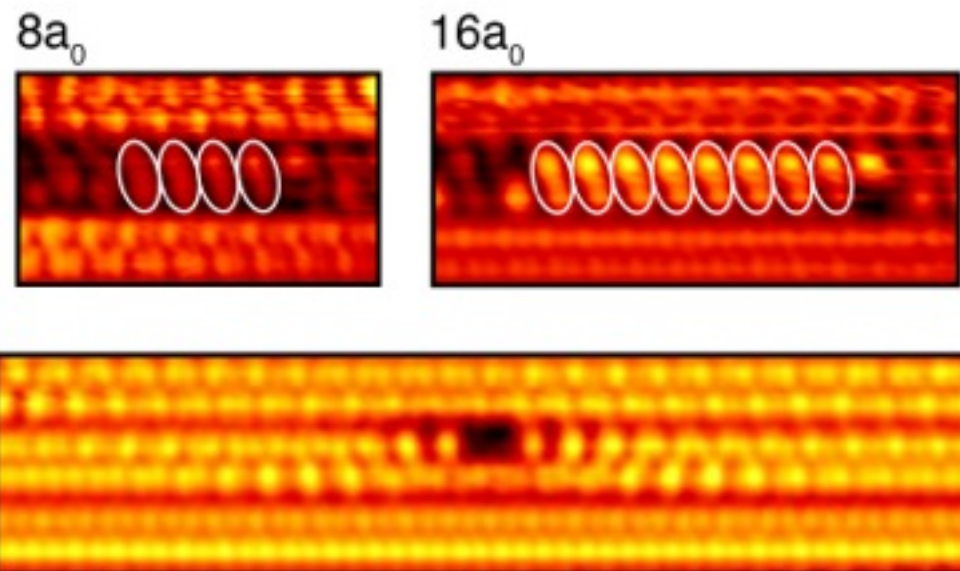
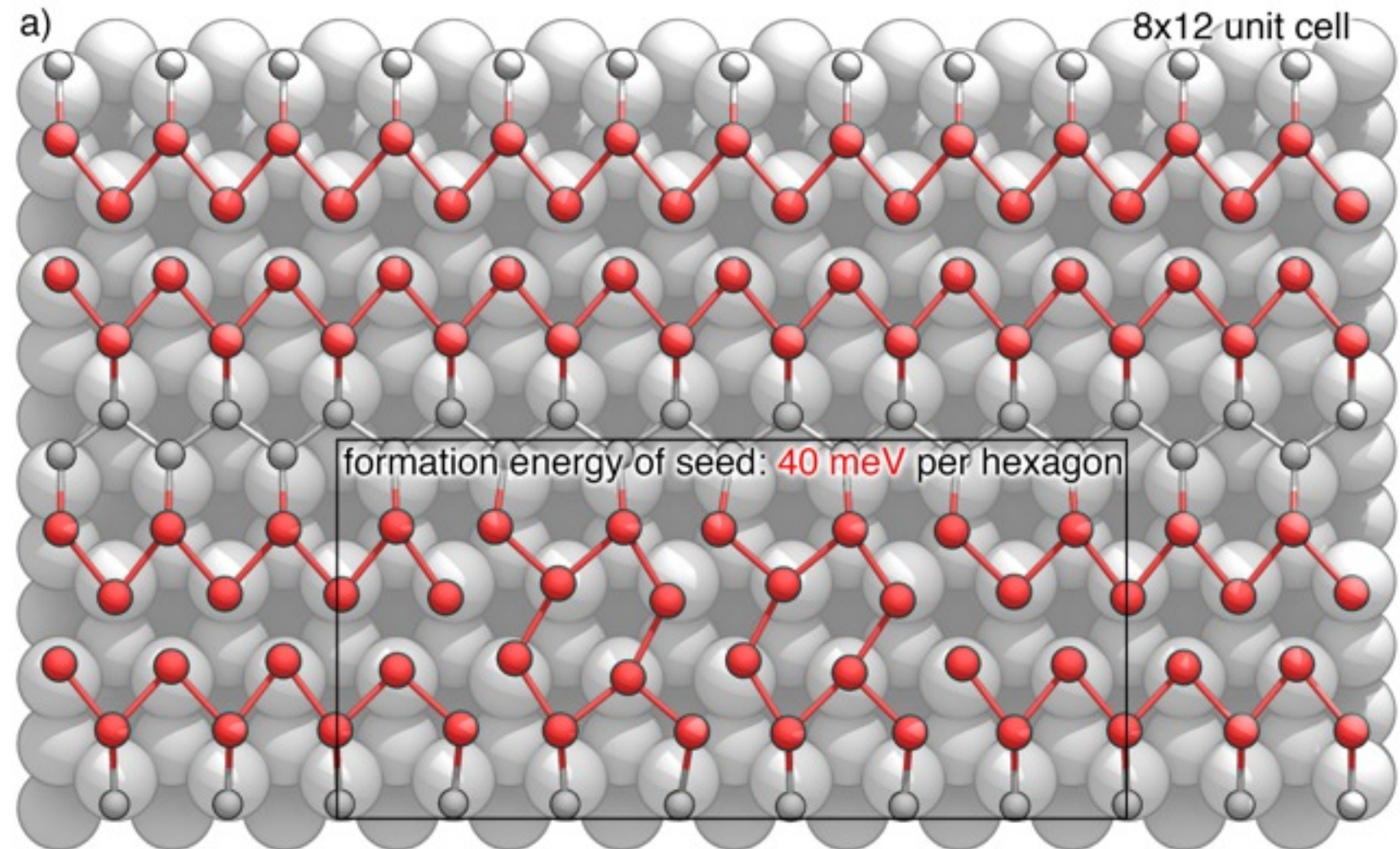
- time-resolved electron diffraction measurements** (M. Horn von Hoegen group) and ***ab initio* molecular dynamics calculations** show freezing triggered by heterogeneous nucleation of ground state at adsorbates

First order transition propagating from seeds at speed of sound (850m/s), in analogy to falling row of dominoes



# Nature of condensation nuclei?

- so far used hexagons as condensation nuclei
- local minimum on potential energy surface, but formation costs 40 meV per hexagon
- attempts to use adatoms, e. g. O, as nuclei resulted in no observable condensation



- Recent experiment by H.W.Yeom shows oxygen to facilitate phase transition, but only for pair-wise oxygen coadsorption!

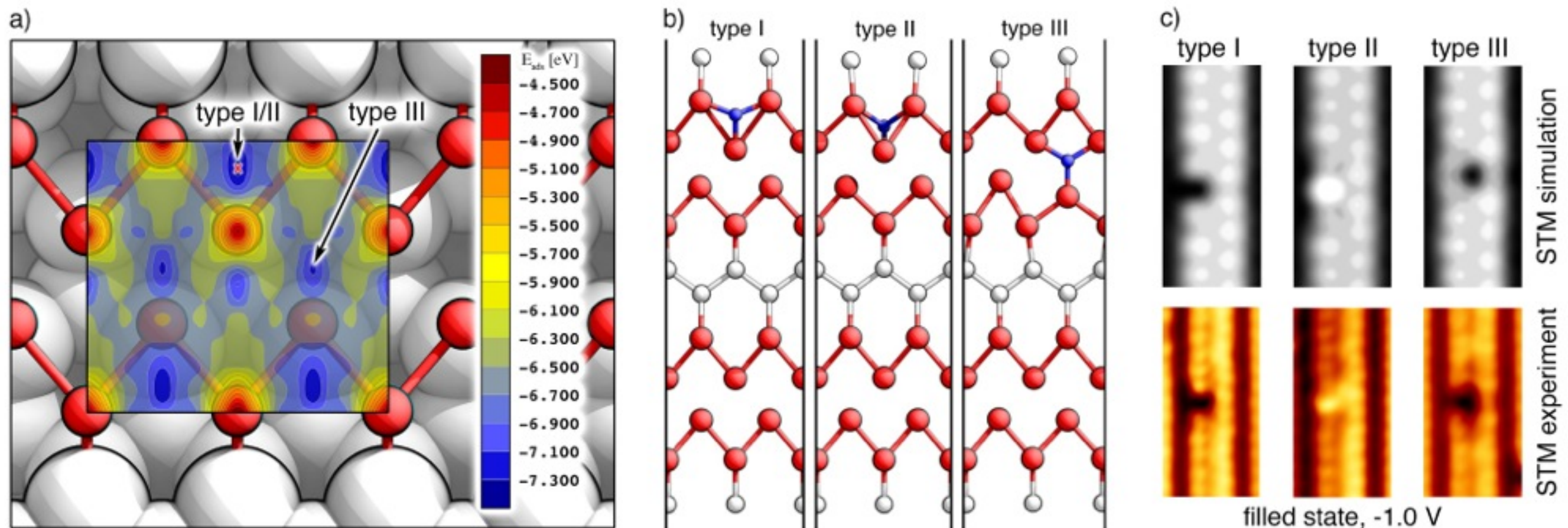
=> Investigate O adatoms on In/Si(111)



# Oxygen on In/Si(111)

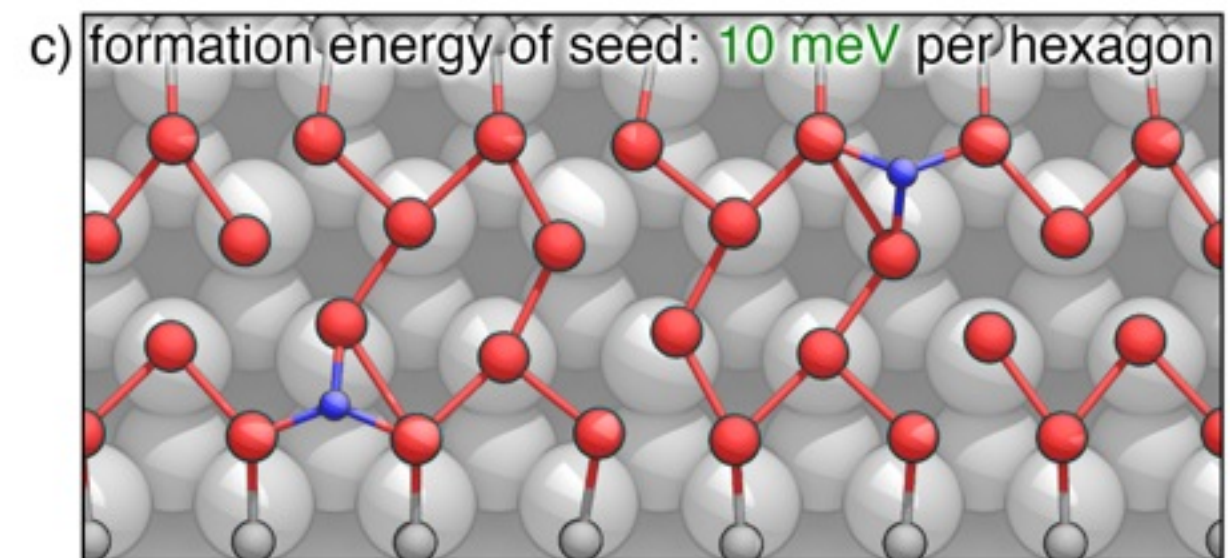
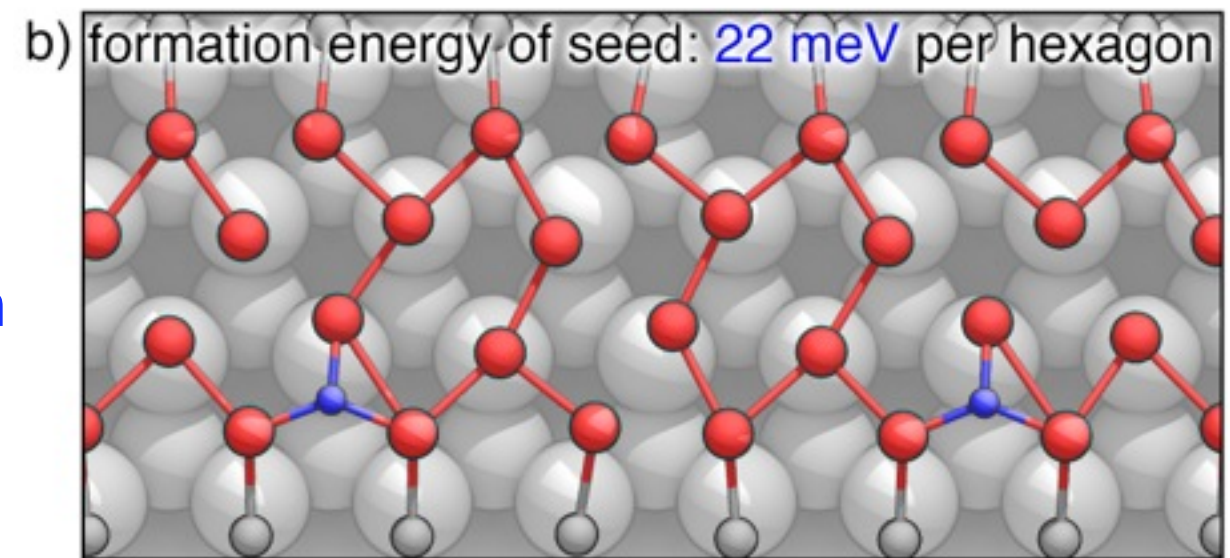
- 3 dominant types of defects observed experimentally, labeled type I, II and III
- Calculate adsorption energy surface, pick 3 energetically most favourable and calculate STM images

=> good agreement with measured STM images, basic adsorption understood



# Oxygen reduces formation energy of seeds

- Experimentally, only type I defects with a spacing of even multiples of  $a_0 = 3.86 \text{ \AA}$  observed to trigger phase transition
- Calculate impact of O adatoms with x4 distance in type I position in  $(8 \times 12)$  unit cell
- O coadsorption at odd multiples of  $a_0$  pulls trimers within hexagons apart by chemical strain, locking structure in  $(4 \times 1)$
- O coadsorption at even multiples of  $a_0$  reduces energy cost for hexagon formation from 40 meV to 22 meV (same chain) or even 10 meV (opposite chain sides)
- Formation energy still positive,  $(4 \times 4)$  hexagon still unstable contrary to experimental observation
- 10 meV per  $(4 \times 2)$  hexagon = 2.5 meV per In atom
- finite size effects, accuracy of DFT-LDA? => could try hybrid DFT with self interaction correction





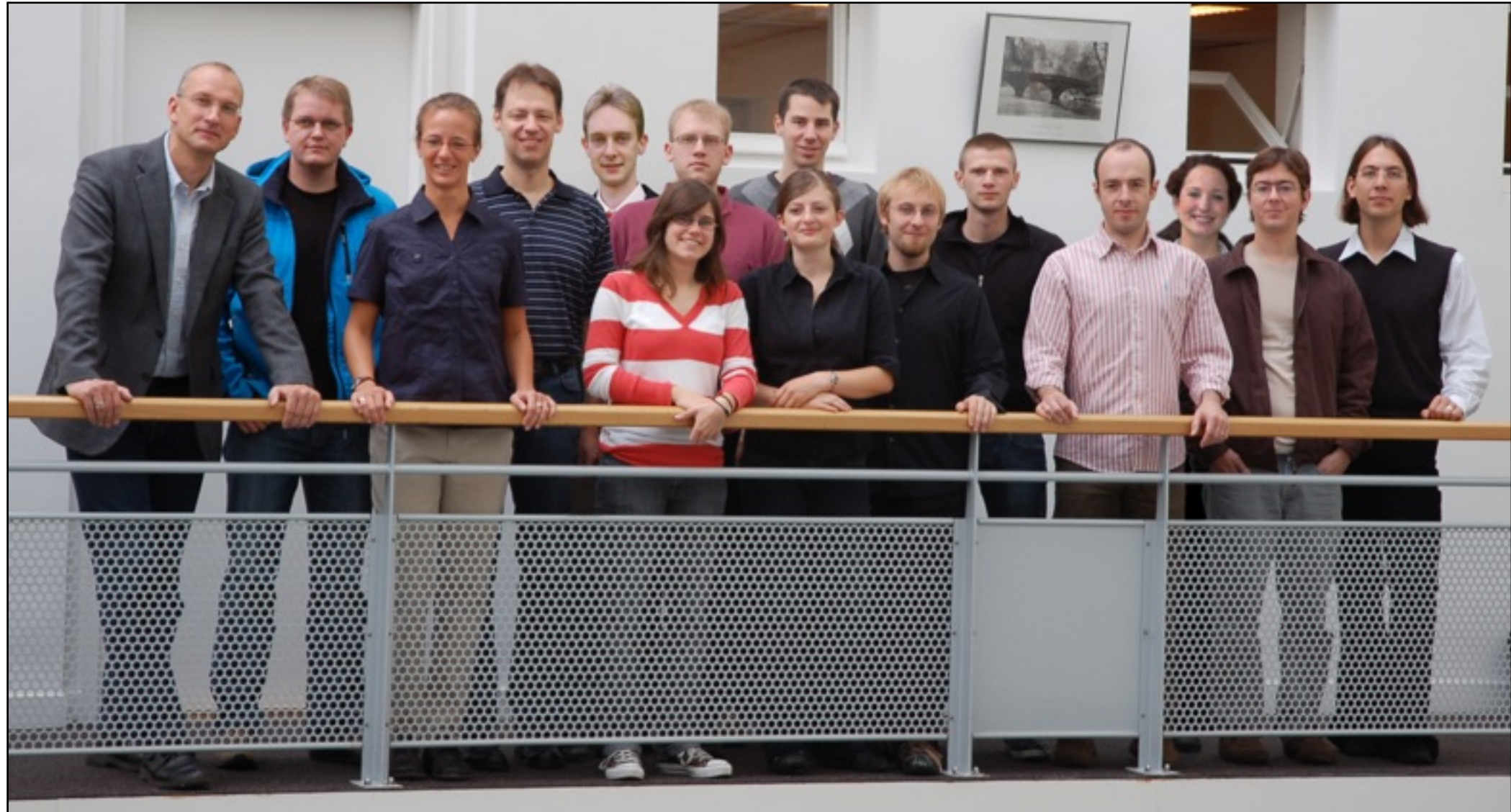
# Summary

- Determined structure of ground state from mid-infrared response  
=> (8x2) hexagon
- Phase transition path described by phonon eigenvectors
- Transition (4x1) → (8x2) is strictly NOT a Peierls transition, but energy gain due to band gap opening in analogy to Peierls transition
- (8x2) → (4x1) transition at finite temperatures explained as subtle interplay between lower total energy of insulating (8x2) hexagon and higher vibrational & electronic entropy of metallic and less tightly bound (4x1) zigzag chain structure
- Phase transition is of first order, propagating from condensation nuclei similar to a row of falling dominoes
- Condensation seeds not consisting of single adsorbates, but two adsorbates acting together (work in progress)

PRL **98**, 026105 (2007), PRL **100**, 106802 (2008),  
PRL **102**, 226805 (2009), PRL **105**, 126102 (2010),  
PRB **84**, 115416 (2011), PRL **109**, 186101 (2012)

# Acknowledgements

Thanks to my coworkers, especially to Wolf Gero Schmidt, his group, and Simone Sanna

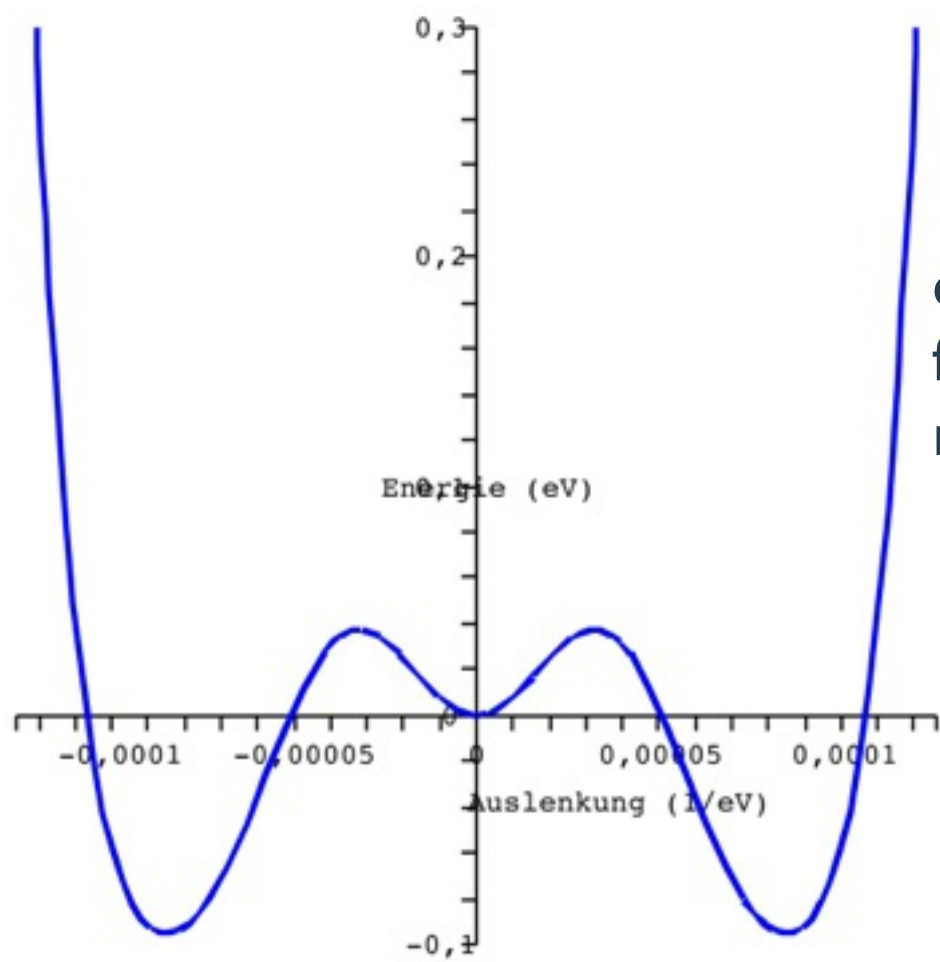


Thanks to our collaborators Friedhelm Bechstedt, John McGilp, Norbert Esser and Han Woong Yeom

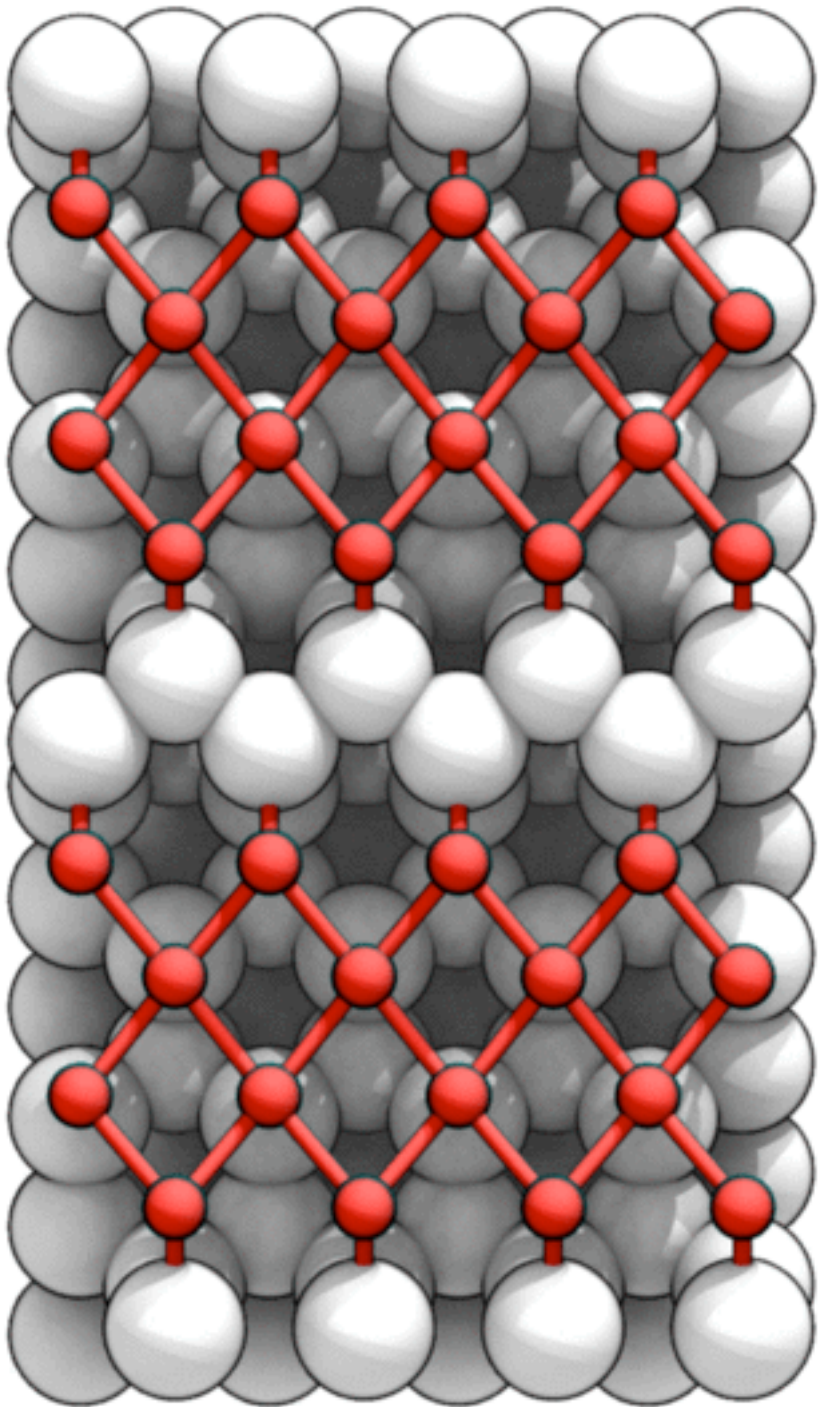


# (4x1) <-> (8x2) Transition path

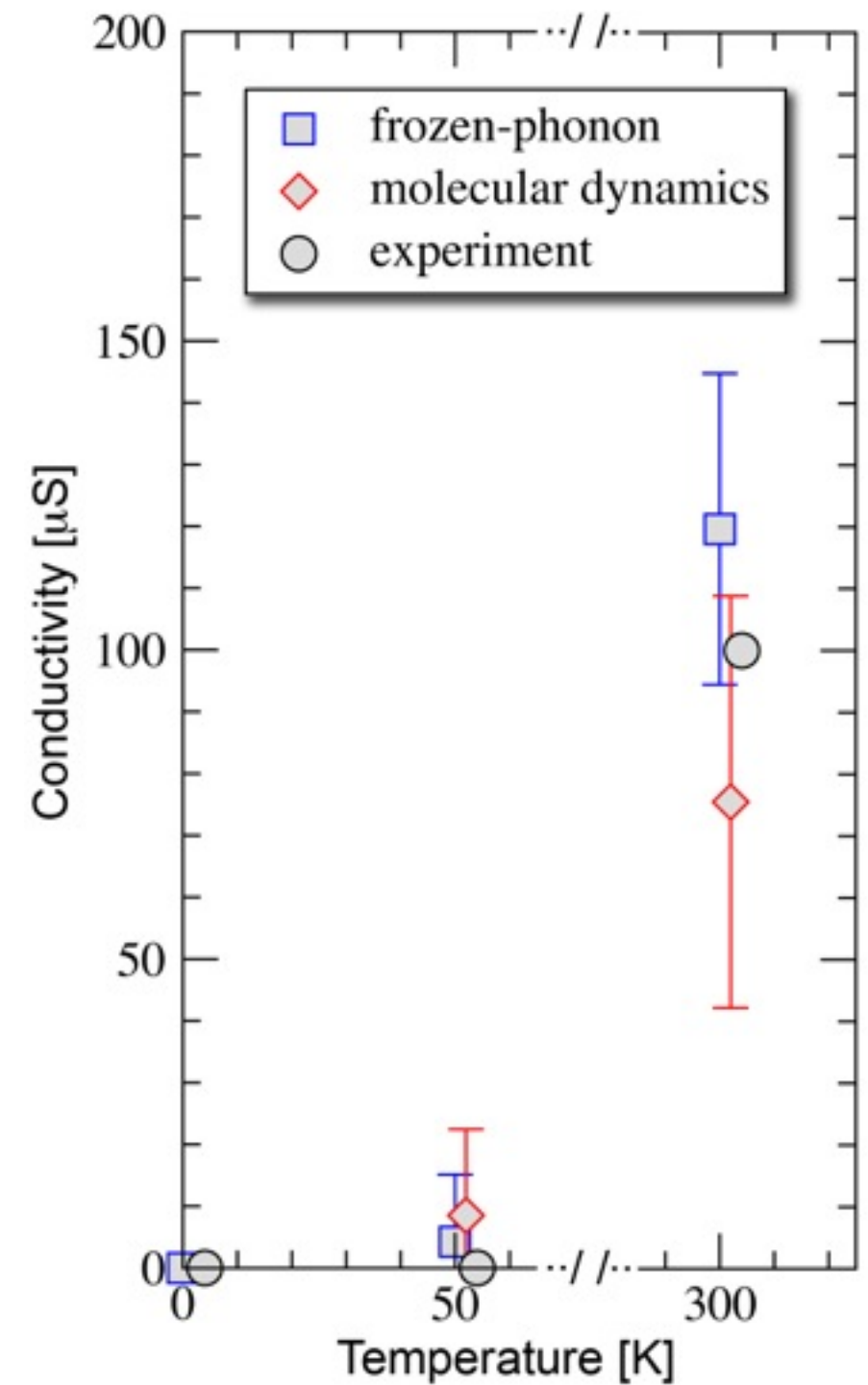
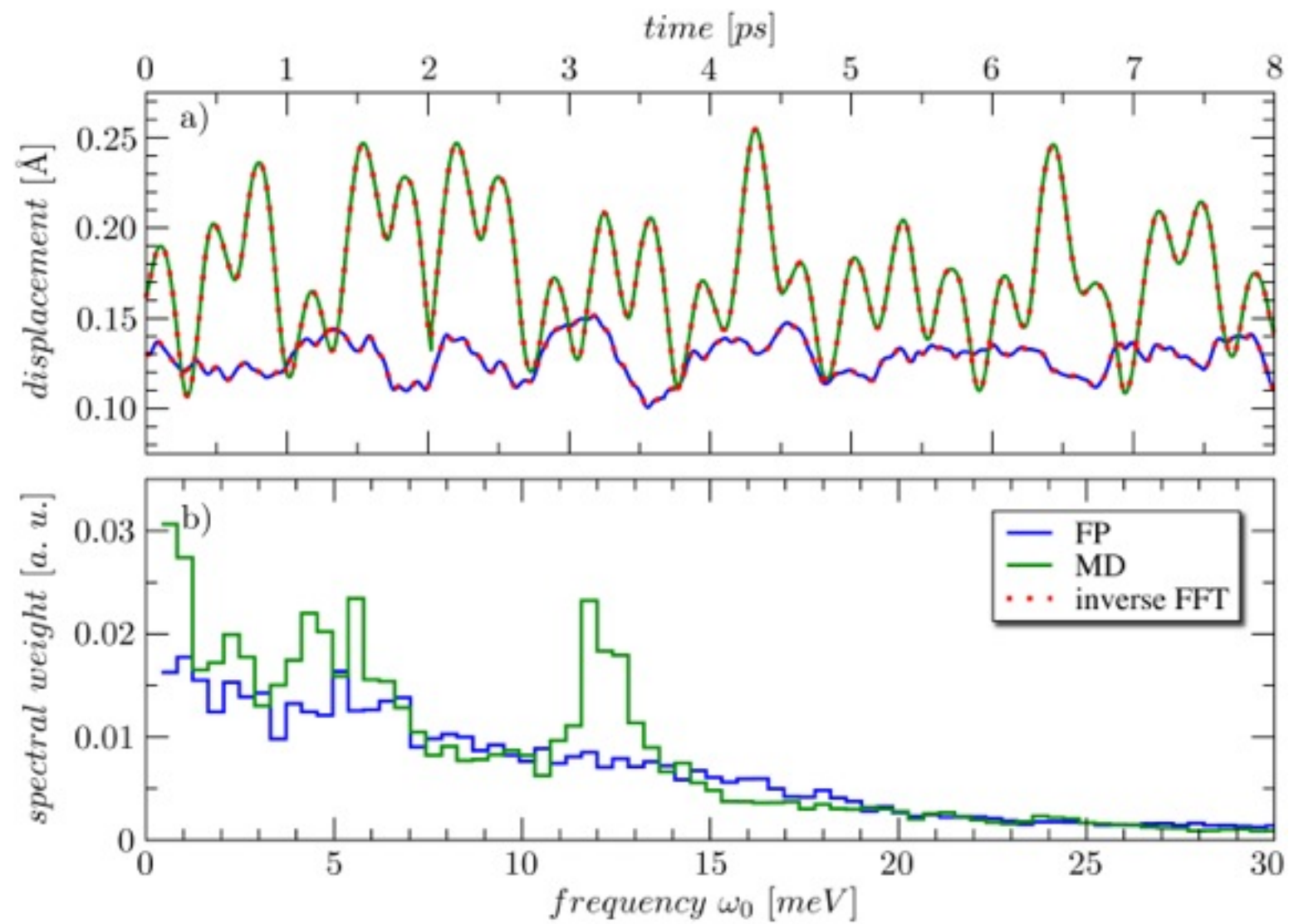
- Obtain transition path from linear combination of frozen-phonon eigenvectors
- Anharmonic effects lead to fluctuation frequency of 16 cm<sup>-1</sup>



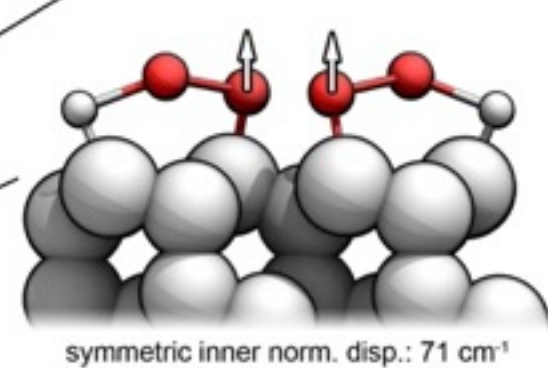
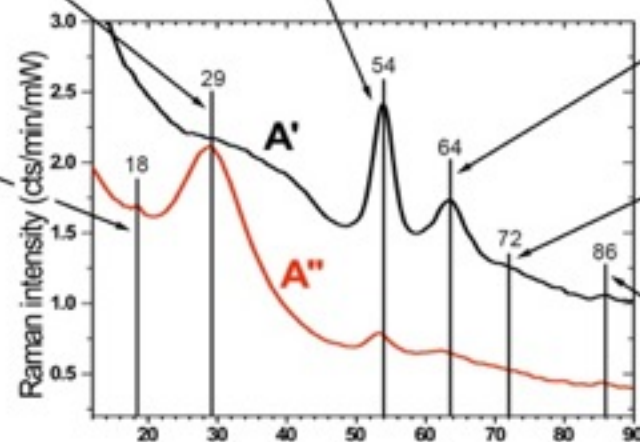
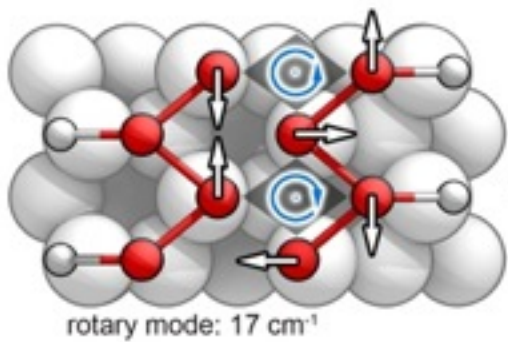
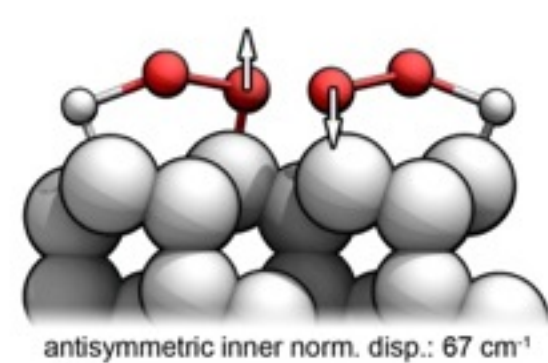
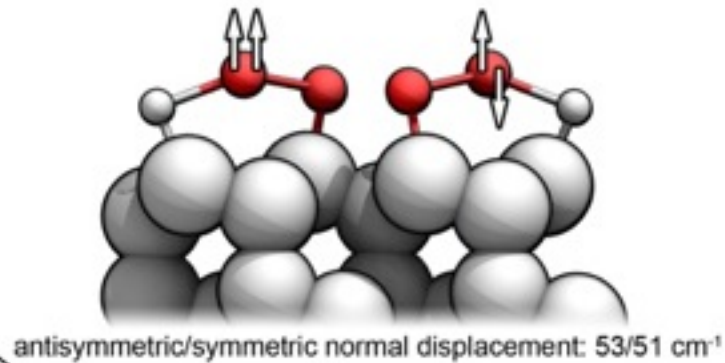
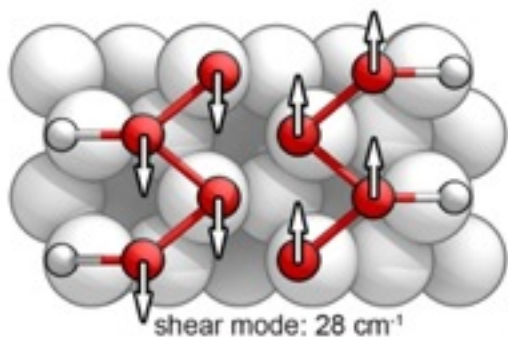
composite potential  
from shear mode +  
rot I + rot II + remaining  
modes



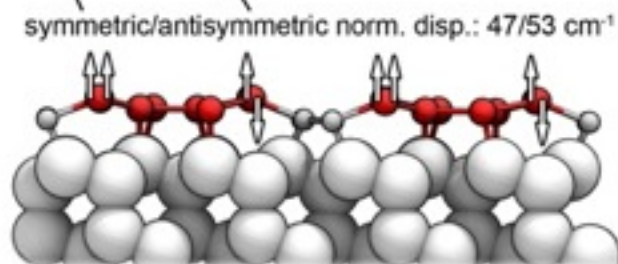
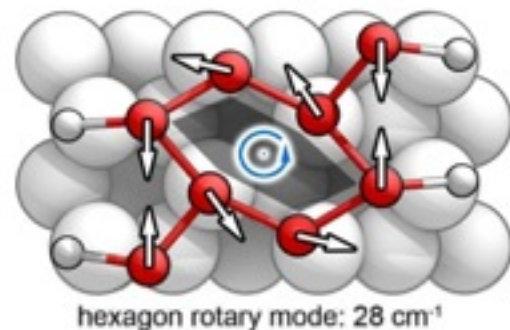
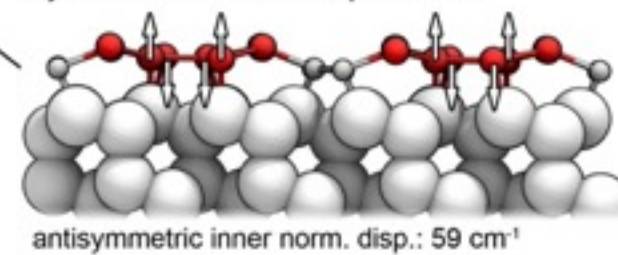
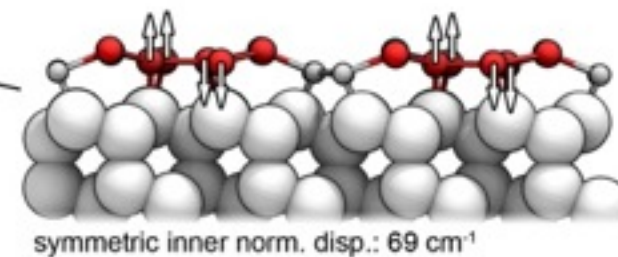
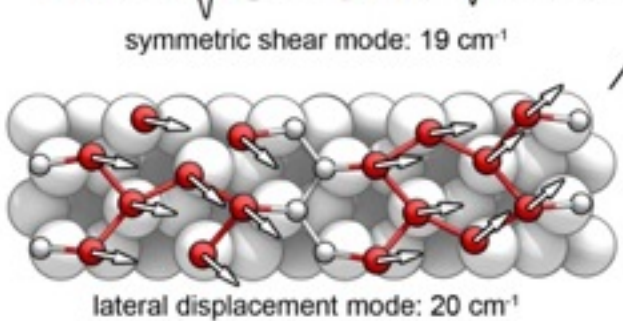
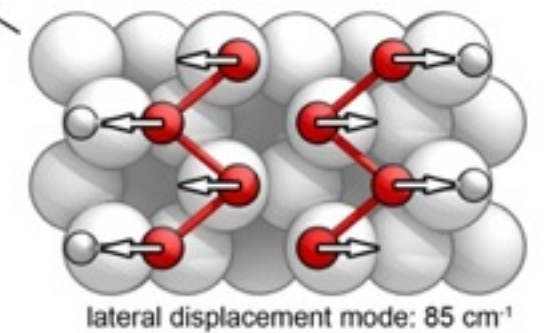
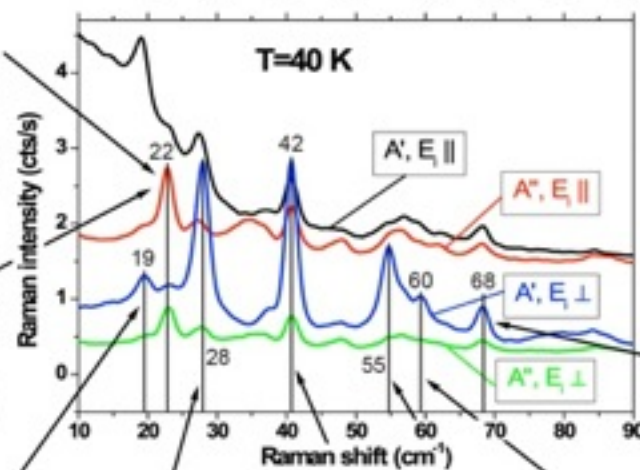
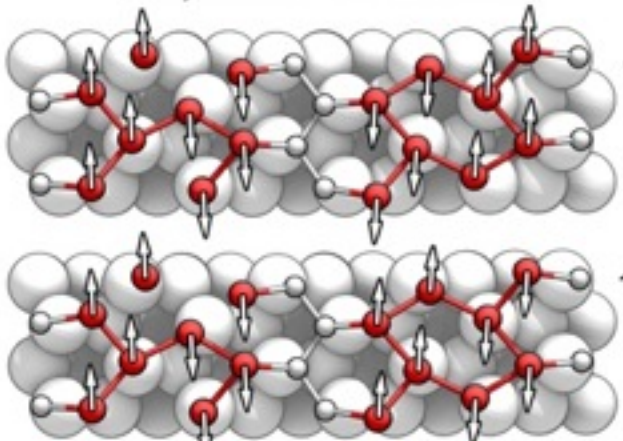
SHEAR MODE	$(8 \times 2) \text{ [cm}^{-1}\text{]}$	$\rightarrow$	$(4 \times 1) \text{ [cm}^{-1}\text{]}$
Experiment	$2 \cdot 23.5 \pm 0.8$	$\rightarrow$	$28 \pm 0.9$
harmonic approx.	18, 19	$\rightarrow$	28
anharmonicities	20	$\rightarrow$	16







antisymmetric shear mode:  $18\text{ cm}^{-1}$







# Density functional theory (DFT):

 Hohenberg-Kohn theorem:

$$E_{XC}[n] \approx E_{XC}^{LDA}[n] = \int n(\mathbf{r}) \epsilon_{XC}^{hom}(n(\mathbf{r})) d\mathbf{r}$$

$$E_e[n] = T_0[n] + \frac{1}{2} \int \frac{n(\mathbf{r})n(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}d\mathbf{r}' + \int n(\mathbf{r})V(\mathbf{r})d\mathbf{r} + E_{XC}[n]$$

[Walter Kohn, Nobel Prize for chemistry in 1998]

  **atomic positions**

Starting point: initial geometry





external potential

interatomic forces

Kohn-Sham **self-consistent**  
electron structure


$$\left\{ -\frac{\nabla^2}{2} + \int \frac{n(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' + V(\mathbf{r}) + \frac{\delta E_{XC}^{LDA}}{\delta n(\mathbf{r})} \right\} \psi_j(\mathbf{r}) = \epsilon_j \psi_j(\mathbf{r})$$

$$n(\mathbf{r}) = \sum_j^{occ.} |\psi_j(\mathbf{r})|^2$$



structurally relaxed ground-state

 vibrational and  
thermal properties

 electronic  
properties

 spectroscopic and  
transport properties



# Excited states (GW/BSE)

- DFT disregards **screened  $e^-e^-$  interaction** and  **$e^-h$  interaction** for **excited states**  $\Rightarrow$  band gap underestimation, wrong distribution of spectral weights
- Perturbative approaches for including screening (GW) and  $e^-h$  interaction (Bethe-Salpeter), starting from Quantum Liouville equation

$$i \frac{d\hat{\rho}(t)}{dt} = [\hat{\mathcal{H}}(t), \hat{\rho}(t)] \quad \rho(\mathbf{r}, \mathbf{r}', t) = \sum_v \phi_v^*(\mathbf{r}, t) \phi_v(\mathbf{r}', t)$$

single particle occ. orbitals

$$\int \hat{\mathcal{H}}(\mathbf{r}, \mathbf{r}', t) \phi(\mathbf{r}', t) d\mathbf{r}' = \left( -\frac{1}{2} \nabla^2 + v_H(\mathbf{r}, t) + v_{ext}(\mathbf{r}, t) \right) \phi(\mathbf{r}, t) \\ + \int \Sigma(\mathbf{r}, \mathbf{r}', t) \phi(\mathbf{r}', t) d\mathbf{r}'$$

time-dep. perturbation, i. e. electromagn. field

self-energy

$$\Sigma_{COH}(\mathbf{r}, \mathbf{r}') = \frac{1}{2} \delta(\mathbf{r} - \mathbf{r}') W_p(\mathbf{r}, \mathbf{r}')$$

$$\Sigma_{SEX}(\mathbf{r}, \mathbf{r}', t) = - \sum_v \phi_v(\mathbf{r}, t) \phi_v^*(\mathbf{r}', t) W(\mathbf{r}, \mathbf{r}')$$

statically screened  
Bethe-Salpeter  
equation (BSE)

screened Coulomb  
interaction



# Excited states (GW/BSE)

- 🌀 To correct for DFT's band gap underestimation, quasiparticle energies can be obtained in GW approximation from

$$\Sigma_{GW}(\mathbf{r}, \mathbf{r}'; i\omega) = \frac{1}{2\pi} \int G(\mathbf{r}, \mathbf{r}'; i(\omega - \omega')) W(\mathbf{r}, \mathbf{r}'; i\omega') d\omega'$$

- 🌀 Screened Coulomb interaction required (in random phase (RPA) approx.)

$$W(\mathbf{r}, \mathbf{r}') = \int \epsilon^{-1}(\mathbf{r}, \mathbf{r}'') v_c(\mathbf{r}'', \mathbf{r}') d\mathbf{r}''$$

- 🌀 Bottleneck: calculation, storage & inversion of dielectric matrix is very computationally demanding, involves large sums over empty states and is hard to converge

- 🌀 Solution: **spectral representation** of RPA dielectric matrix; obtain matrix from **directly calculating eigenvectors and eigenvalues**

$$\tilde{\epsilon} = \sum_{i=1}^N \tilde{\mathbf{v}}_i \lambda_i \tilde{\mathbf{v}}_i^H = \sum_{i=1}^N \tilde{\mathbf{v}}_i (\lambda_i - 1) \tilde{\mathbf{v}}_i^H + I$$

=> no summation over empty states, no inversion, storage of eigenvector/-value pairs only!



# How to calculate the screening

- Obtaining the eigenvectors/-values does NOT require explicit knowledge of the matrix; knowledge of the action of the matrix on an arbitrary vector is sufficient!
- in linear response:  $(\epsilon - I)\Delta V_{SCF} = -v_c\Delta n$
- charge density response  $\Delta n$  to perturbation of self-consist. field  $\Delta V_{SCF}$  can be evaluated from density functional perturbation theory
- orthogonal iteration procedure to obtain eigenvectors/-values, using  $\Delta V_{SCF}$  as trial potentials
- in RPA fast monotonous decay of dielectric eigenvalue spectrum
- single parameter  $N_{eig}$  to control numerical accuracy

$$\tilde{\epsilon} = \sum_{i=1}^N \tilde{\mathbf{v}}_i \lambda_i \tilde{\mathbf{v}}_i^H = \sum_{i=1}^N \tilde{\mathbf{v}}_i (\lambda_i - 1) \tilde{\mathbf{v}}_i^H + I$$

